Series RQSP4/4

प्रश्न-पत्र कोड Q.P. Code

55/4/3

रोल नं.				
Roll No.				

परीक्षार्थी प्रश्न-पत्र कोड को उत्तर-पुस्तिका के मुख-पृष्ठ पर अवश्य लिखें।

Candidates must write the Q.P. Code on the title page of the answer-book.



भौतिक विज्ञान (सैद्धान्तिक) PHYSICS (Theory)

निर्धारित समय: 3 घण्टे अधिकतम अंक : 70

Time allowed: 3 hours Maximum Marks: 70

नोट	NOTE
(I) कृपया जाँच कर लें कि इस प्रश्न-पत्र में मुद्रित पृष्ठ 23 हैं।	(I) Please check that this question paper contains 23 printed pages.
(II) कृपया जाँच कर लें कि इस प्रश्न-पत्र में 33 प्रश्न हैं।	(II) Please check that this question paper contains 33 questions.
(III) प्रश्न-पत्र में दाहिने हाथ की ओर दिए गए प्रश्न- पत्र कोड को परीक्षार्थी उत्तर-पुस्तिका के मुख- पृष्ठ पर लिखें। (IV) कृपया प्रश्न का उत्तर लिखना शुरू करने से पहले,	(III) Q.P. Code given on the right hand side of the question paper should be written on the title page of the answer-book by the candidate.(IV) Please write down the serial
उत्तर-पुस्तिका में प्रश्न का क्रमांक अवश्य लिखें। (V) इस प्रश्न-पत्र को पढ़ने के लिए 15 मिनट का	number of the question in the answer-book before attempting it.

2155/4/3

P.T.O.





सामान्य निर्देश:

निम्नलिखित निर्देशों को बहुत सावधानी से पढ़िए और उनका पालन कीजिए:

- (i) इस प्रश्न-पत्र में 33 प्रश्न हैं। सभी प्रश्न अनिवार्य हैं।
- (ii) प्रश्न-पत्र **पाँच** खण्डों में विभाजित है खण्ड-**क, ख, ग, घ** तथा **ङ** /
- (iii) **खण्ड क –** प्रश्न संख्या 1 से 16 तक बहुविकल्पीय प्रकार के प्रश्न हैं। प्रत्येक प्रश्न 1 अंक का है।
- (iv) **खण्ड ख –** प्रश्न संख्या 17 से 21 तक अति लघु-उत्तरीय प्रकार के प्रश्न हैं । प्रत्येक प्रश्न 2 अंकों का है ।
- (v) **खण्ड ग –** प्रश्न संख्या 22 से 28 तक लघु उत्तरीय प्रकार के प्रश्न हैं। प्रत्येक प्रश्न 3 अंकों का है।
- (vi) $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \$ $\ \ \,$ $\ \$ $\ \ \,$ $\ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \ \,$ $\ \,$ $\ \ \,$ $\ \,$ $\ \,$ $\ \,$ $\ \,$ $\ \,$ $\ \,$ $\$
- (vii) **खण्ड ङ –** प्रश्न संख्या 31 से 33 तक दीर्घ–उत्तरीय प्रकार के प्रश्न हैं। प्रत्येक प्रश्न 5 अंकों का है।
- (viii) प्रश्न-पत्र में समग्र विकल्प नहीं दिया गया है। यद्यपि, खण्ड-**क** के अतिरिक्त अन्य खण्डों के कुछ प्रश्नों में आंतरिक विकल्प का चयन दिया गया है।
- (ix) ध्यान दें कि **दृष्टिबाधित परीक्षार्थियों** के लिए एक अलग प्रश्न-पत्र है।
- (x) कैल्कुलेटर का उपयोग वर्जित है।

जहाँ आवश्यक हो, आप निम्नलिखित भौतिक नियतांकों के मानों का उपयोग कर सकते हैं :

$$c = 3 \times 10^8 \text{ m/s}$$

$$h = 6.63 \times 10^{-34} \text{ Js}$$

$$e = 1.6 \times 10^{-19} C$$

$$\mu_0 = 4\pi \times 10^{-7} \text{ T m A}^{-1}$$

$$\varepsilon_0 = 8.854 \times 10^{-12} \ \mathrm{C^2 \ N^{-1} \ m^{-2}}$$

$$\frac{1}{4\pi\epsilon_0}$$
 = 9 × 10⁹ N m² C⁻²

इलेक्ट्रॉन का द्रव्यमान $(m_e) = 9.1 \times 10^{-31} \ \mathrm{kg}$

न्यूट्रॉन का द्रव्यमान =
$$1.675 \times 10^{-27} \text{ kg}$$

प्रोटॉन का द्रव्यमान =
$$1.673 \times 10^{-27} \text{ kg}$$

आवोगाद्रो संख्या = 6.023×10^{23} प्रति ग्राम मोल

बोल्ट्ज़मान नियतांक = $1.38 \times 10^{-23} \, \mathrm{JK^{-1}}$

2155/4/3



General Instructions:

Read the following instructions very carefully and follow them:

- (i) This question paper contains 33 questions. All questions are compulsory.
- (ii) Question paper is divided into **FIVE** sections Section **A**, **B**, **C**, **D** and **E**.
- (iii) Section A Question number 1 to 16 are Multiple Choice (MCQ) type questions. Each question carries 1 mark.
- (iv) Section B Question number 17 to 21 are Very Short Answer type questions. Each question carries 2 mark.
- (v) Section C Question number 22 to 28 are Short Answer type questions. Each question carries 3 mark.
- (vi) Section D: Question number 29 and 30 are Case-Based questions. Each question carries 4 mark.
- (vii) Section E Question number 31 to 33 are Long Answer type questions. Each question carries 5 mark.
- (viii) There is no overall choice given in the question paper. However, an internal choice has been provided in few questions in all the Sections except Section—A.
- (ix) Kindly note that there is a separate question paper for Visually Impaired candidates.
- (x) Use of calculators is NOT allowed.

You may use the following values of physical constants wherever necessary:

$$c = 3 \times 10^8 \text{ m/s}$$

$$h = 6.63 \times 10^{-34} Js$$

$$e = 1.6 \times 10^{-19} C$$

$$\mu_0 = 4\pi \times 10^{-7} \text{ T m A}^{-1}$$

$$\varepsilon_0 = 8.854 \times 10^{-12} \ \mathrm{C^2 \ N^{-1} \ m^{-2}}$$

$$\frac{1}{4\pi\epsilon_0}$$
 = 9 × 10⁹ N m² C⁻²

Mass of electron (m_e) = 9.1×10^{-31} kg

Mass of neutron = $1.675 \times 10^{-27} \text{ kg}$

Mass of proton = 1.673×10^{-27} kg

Avogadro's number = 6.023×10^{23} per gram mole

Boltzmann constant = $1.38 \times 10^{-23} \, \mathrm{JK^{-1}}$

2155/4/3 P.T.O.



1

1

1

- द्विध्रुव आघूर्ण \overrightarrow{p} का कोई विद्युत द्विध्रुव किसी एकसमान विद्युत क्षेत्र \overrightarrow{E} में रखा है। इस द्विध्रुव को 1. इसके स्थायी साम्य की स्थिति से अस्थायी साम्य की स्थिति तक घूर्णित कराने में किया गया कार्य है
 - 2 pE(A)

(B) -2 pE

(C) pE

- (D) श्रन्य
- आवेश घनत्व λ का कोई अनन्त लम्बा सीधा तार x-y-तल में y'y अक्ष के अनुदिश रखा है । 2. बिन्दु P(x, 0) पर स्थित बिन्दु आवेश q पर कूलॉम बल होगा
 - (A) आकर्षिक और $rac{{
 m q} \lambda}{2\pi {
 m e}_0 x}$
- (B) प्रतिकर्षिक और $\frac{q\lambda}{2\pi\epsilon_0 x}$

- (C) आकर्षिक और $\frac{q\lambda}{\pi \epsilon_0 x}$
- (D) प्रतिकर्षिक और $\frac{q\lambda}{\pi\epsilon_0 x}$
- ightarrowig3. के बीच कलान्तर होता है –
 - (A) शून्य

(B) π

(C) $\frac{\pi}{2}$

- (D) $\frac{\pi}{4}$
- हाइड्रोजन परमाणु की बामर श्रेणी में, जैसे ही स्पेक्ट्रमी रेखाओं की तरंगदैर्घ्य घटती है वह प्रतीत होती हैं 4. 1

- (A) समान दूरी और समान तीव्रता
- (B) एक-दूसरे से अधिक दूरी पर तथा तीव्रता में अधिक प्रबल
- (C) एक-दूसरे के निकट दूरी पर तथा तीव्रता में अधिक प्रबल
- (D) एक-दूसरे के निकट दूरी पर तथा तीव्रता में अधिक दुर्बल
- एक-दूसरे से दूरी ${f r}$ पर स्थित दो लम्बे सीधे समान्तर चालकों ${f A}$ और ${f B}$ से धारा ${f I}$ विपरीत दिशाओं में 5. प्रवाहित हो रही है। कोई तीसरा सर्वसम चालक ${
 m C}$ चालक ${
 m A}$ से $\left(rac{{
 m r}}{3}
 ight)$ दूरी पर स्थित है तथा इससे धारा ${
 m I}_1$ उसी दिशा में प्रवाहित हो रही है जिसमें चालक ${
 m A}$ में प्रवाहित हो रही है। चालक ${
 m C}$ की एकांक लम्बाई पर नेट चुम्बकीय बल है –
 - (A) $\frac{3\mu_0 I I_1}{2\pi r}$, A की ओर
- (B) $\frac{3\mu_0 I I_1}{2\pi r}$, B की ओर
- (C) $\frac{3\mu_0 I I_1}{4\pi r}$, A की ओर
- $(\mathrm{D})~~ rac{3\mu_0\mathrm{I}~\mathrm{I}_1}{4\pi r}\,,\,\mathrm{B}$ की ओर

2155/4/3

SECTION - A

 $16 \times 1 = 16$

1

1

1

- An electric dipole of dipole moment \overrightarrow{p} is kept in a uniform electric field 1.
 - E. The amount of work done to rotate it from the position of stable equilibrium to that of unstable equilibrium will be
 - (A) 2 pE

(B) -2 pE

(C) pE

- (D) zero
- 2. An infinite long straight wire having a charge density λ is kept along y'y axis in x-y plane. The Coulomb force on a point charge q at a point P (x, 0)will be
 - (A) attractive and $\frac{q\lambda}{2\pi\epsilon_0 x}$
 - (B) repulsive and $\frac{\mathrm{q}\lambda}{2\pi\epsilon_0 x}$ (D) repulsive and $\frac{\mathrm{q}\lambda}{\pi\epsilon_0 x}$
 - (C) attractive and $\frac{q\lambda}{\pi\epsilon_0 x}$
- The phase difference between electric field E and magnetic field B in an 3. electromagnetic wave propagating along z-axis is –
 - (A) zero

(C)

- (D) $\frac{\pi}{4}$
- 4. In Balmer series of hydrogen atom, as the wavelength of spectral lines decreases, they appear
 - 1

- equally spaced and equally intense. (A)
- further apart and stronger in intensity. (B)
- (C) closer together and stronger in intensity.
- (D) closer together and weaker in intensity.
- 5. Two long straight parallel conductors A and B, kept at a distance r, carry current I in opposite directions. A third identical conductor C, kept at a distance $\left(\frac{\mathbf{r}}{2}\right)$ from A carry current \mathbf{I}_1 in the same direction as in A. The
 - net magnetic force on unit length of C is

1

- (A) $\frac{3\mu_0 I I_1}{2\pi r}$, towards A
- (B) $\frac{3\mu_0 I I_1}{2\pi r}$, towards B
- (C) $\frac{3\mu_0 l l_1}{4\pi r}$, towards A
- (D) $\frac{3\mu_0 I I_1}{4\pi r}$, towards B

2155/4/3

5

P.T.O.

(A)
$$t = \frac{nT}{8}$$

(B)
$$t = \frac{nT}{4}$$

(C)
$$t = \frac{nT}{2}$$

(D)
$$t = nT$$

यहाँ, n = 1, 2, 3, 4, ...

7. त्रिज्या R के किसी वृत्ताकार पाश A से कोई धारा I प्रवाहित हो रही है । त्रिज्या $\mathbf{r} \bigg(= \frac{R}{20} \bigg)$ के किसी वृत्ताकार पाश B को A के तल में संकेन्द्री रखा गया है । पाश B से संबद्ध चुम्बकीय फ्लक्स निम्नलिखित में किसके अनुक्रमानुपाती है ?

1

(B)
$$\sqrt{R}$$

(C)
$$R^{\frac{3}{2}}$$

(D)
$$R^2$$

8. किसी गैल्वैनोमीटर को जिसका प्रतिरोध 100 Ω है, 0.1 Ω के प्रतिरोध का उपयोग करके (0 – 1 A) पिरसर के एमीटर में पिरवर्तित किया गया है। यह जिस धारा के लिए पूर्ण पैमाना विक्षेपण दर्शाएगा, वह धारा है लगभग

1

9. किसी दी गयी धारा i = $(i_1\cos\omega t + i_2\sin\omega t)$ का r.m.s. मान है –

(A)
$$\frac{1}{\sqrt{2}} (i_1 + i_2)$$

(B)
$$\frac{1}{\sqrt{2}} (i_1 - i_2)$$

(C)
$$\frac{1}{\sqrt{2}}\sqrt{(i_1^2+i_2^2)}$$

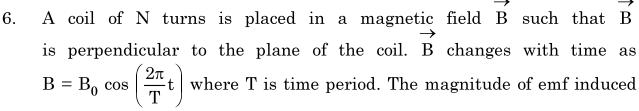
(D)
$$\frac{1}{\sqrt{2}}(i_1^2 + i_2^2)$$

10. प्रकाश की क्वान्टम प्रकृति प्रकाशविद्युत प्रभाव की व्याख्या इस प्रकार करती है –

1

- (A) आपितत विकिरणों की कोई निम्नतम आवृत्ति होती है जिससे कम पर कोई इलेक्ट्रॉन उत्सर्जित नहीं होते।
- (B) फोटो-इलेक्ट्रॉनों की अधिकतम गतिज ऊर्जा केवल आपतित विकिरणों की आवृत्ति पर निर्भर करती है।
- (C) जब धातु-पृष्ठ को प्रदीप्त किया जाता है तो कुछ समय पश्चात् पृष्ठ से इलेक्ट्रॉन उत्सर्जित होते हैं।
- (D) प्रकाश विद्युत धारा आपतित विकिरणों की तीव्रता पर निर्भर नहीं करती है।

2155/4/3



in the coil will be maximum at

(A) $t = \frac{nT}{8}$

(B) $t = \frac{nT}{4}$

(C) $t = \frac{nT}{2}$

(D) t = nT

Here, n = 1, 2, 3, 4, ...

7. A circular loop A of radius R carries a current I. Another circular loop B of radius $r = \frac{R}{20}$ is placed concentrically in the plane of A. The magnetic

flux linked with loop B is proportional to

(A) R (B) \sqrt{R}

(C) $R^{\frac{3}{2}}$

(D) R^2

A galvanometer of resistance 100 Ω is converted into an ammeter of range 8. (0-1 A) using a resistance of 0.1 Ω . The ammeter will show full scale deflection for a current of about

 $(A) \quad 0.1 \text{ mA}$

(B) 1 mA

(C) 10 mA (D) 0.1 A

The r.m.s. value of a current given by $i = (i_1 \cos \omega t + i_2 \sin \omega t)$ is – 9.

(A) $\frac{1}{\sqrt{2}}$ (i₁ + i₂)

(B) $\frac{1}{\sqrt{2}} (i_1 - i_2)$

(C) $\frac{1}{\sqrt{2}}\sqrt{(i_1^2+i_2^2)}$

(D) $\frac{1}{\sqrt{2}}(i_1^2 + i_2^2)$

The quantum nature of light explains the observations on photoelectric 10. effect as –

1

1

1

1

there is a minimum frequency of incident radiation below which no electrons are emitted.

(B) the maximum kinetic energy of photoelectrons depends only on the frequency of incident radiation.

when the metal surface is illuminated, electrons are ejected from the (C) surface after sometime.

the photoelectric current is independent of the intensity of incident radiation.

- 11. किसी प्रतिचुम्बकीय पदार्थ की चुम्बकीय प्रवृत्ति होती है (A) कम और ऋणात्मक (B) कम और धनात्मक (C) अधिक और ऋणात्मक (D) अधिक और धनात्मक 12. हाइड्रोजन परमाणु के बोर-मॉडल में nवीं कक्षा की त्रिज्या (\mathbf{r}_n) n के साथ िकस प्रकार विचरण करती है ? (A) $\mathbf{r}_n \propto \mathbf{n}$ (B) $\mathbf{r}_n \propto \frac{1}{\mathbf{n}}$ (C) $\mathbf{r}_n \propto \mathbf{n}^2$ (D) $\mathbf{r}_n \propto \frac{1}{\mathbf{n}^2}$ नोट : प्रश्न संख्या 13 से 16 में दो कथन दिए गए हैं एक को अभिकथन (A) तथा दूसरे को कारण (R) लेबल किया गया है । इन प्रश्नों के सही उत्तरों का नीचे दिए कोड (A), (B), (C) और
 - (A) अभिकथन (A) और कारण (R) दोनों सत्य हैं और कारण (R) अभिकथन (A) की सही व्याख्या है।
 - (B) अभिकथन (A) और कारण (R) दोनों सत्य हैं और कारण (R) अभिकथन (A) की सही व्याख्या नहीं है।
 - (C) अभिकथन (A) सत्य है और कारण (R) असत्य है।

(D) में से चयन कीजिए:

- (D) यदि दोनों अभिकथन (A) और कारण (R) असत्य हैं।
- 13. **अभिकथन (A) :** जब किसी चालक में इलेक्ट्रॉन का अपवाह होता है तो इसका यह अर्थ नहीं होता है कि उस चालक के सभी मुक्त इलेक्ट्रॉन समान दिशा में गतिमान हैं।
 - कारण (R): अपवाह वेग इलेक्ट्रॉनों के बृहत् यादृच्छिक वेगों पर अध्यारोपित होता है।
- 14. अभिकथन (A): प्रकाश के व्यतिकरण और विवर्तन में प्रकाश ऊर्जा एक प्रदेश में घट जाती है और कोई काली फ्रिंज उत्पन्न करती है। िकसी अन्य प्रदेश में यह बढ़ जाती है और कोई चमकीली फ्रिंज उत्पन्न करती है।
 - कारण (R): ऐसा इस कारण से होता है, क्योंकि व्यतिकरण और विवर्तन की परिघटनाओं में ऊर्जा का संरक्षण नहीं होता है।
- 15. **अभिकथन (A) :** धातुओं के लिए प्रतिरोध ताप गुणांक धनात्मक तथा p-प्रकार के अर्धचालकों के लिए प्रतिरोध ताप गुणांक ऋणात्मक होता है ।
 - कारण (R): धातुओं में आवेश वाहक ऋणावेशित होते हैं जबिक p-प्रकार के अर्धचालकों में बहुसंख्यक आवेश वाहक धनावेशित होते हैं।
- 16. **अभिकथन (A) :** पीले प्रकाश द्वारा किरणित किए जाने पर जिंक के पृष्ठ से इलेक्ट्रॉनों का उत्सर्जन होता है।
- कारण (R) : जिंक के कार्यफलन की तुलना में पीले प्रकाश के फोटॉन से संबद्ध ऊर्जा अधिक होती है। 1

1

1

1

1

- 11. The magnetic susceptibility for a diamagnetic material is
 - (A) small and negative
- (B) small and positive

1

1

1

1

1

- (C) large and negative
- (D) large and positive
- 12. The radius (r_n) of n^{th} orbit in Bohr model of hydrogen atom varies with n as
 - (A) $r_n \propto n$

(B) $r_n \propto \frac{1}{n}$

(C) $r_n \propto n^2$

(D) $r_n \propto \frac{1}{n^2}$

Note: For questions number 13 to 16, two statements are given — one labelled Assertion (A) and the other labelled Reason (R). Select the correct answer to these questions from the codes (A), (B), (C) and (D) as given below:

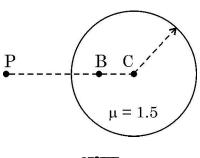
- (A) If both Assertion (A) and Reason (R) are true and Reason (R) is the correct explanation of Assertion (A).
- (B) If both Assertion (A) and Reason (R) are true and Reason (R) is not the correct explanation of Assertion (A).
- (C) If Assertion (A) is true and Reason (R) is false.
- (D) If both Assertion (A) and Reason (R) are false.
- 13. **Assertion (A):** When electrons drift in a conductor, it does not mean that all free electrons in the conductor are moving in the same direction.
 - Reason (R): The drift velocity is superposed over large random velocities of electrons.

14. **Assertion (A)**: In interference and diffraction of light, light energy reduces in one region producing a dark fringe. It increases in another region and produces a bright fringe.

- **Reason (R):** This happens because energy is not conserved in the phenomena of interference and diffraction.
- 15. **Assertion (A):** The temperature coefficient of resistance is positive for metals and negative for p-type semiconductors.
 - **Reason (R):** The charge carriers in metals are negatively charged, whereas the majority charge carriers in p-type semiconductors are positively charged.
- 16. **Assertion (A):** Electrons are ejected from the surface of zinc when it is irradiated by yellow light.
 - Reason (R): Energy associated with a photon of yellow light is more than the work function of zinc.
- 2155/4/3 9 P.T.O.



17. (a) आरेख में दर्शाए अनुसार अपवर्तनांक 1.5 और त्रिज्या $40~{
m cm}$ के किसी काँच के गोले में कोई वायु का बुलबुला बिन्दु $B~(CB=20~{
m cm})$ पर फंस गया है । बिन्दु P से प्रेक्षण करने पर इस बुलबुले के प्रतिबिम्ब की प्रकृति और स्थिति ज्ञात कीजिए ।



अथवा

(b) किसी अपवर्ती दूरदर्शक के सामान्य समायोजन में अभिदृश्यक और अभिनेत्र लेंस के बीच की दूरी $1.00~\mathrm{m}$ है। यदि इस दूरदर्शक की आवर्धन क्षमता 19 है, तो अभिदृश्यक और अभिनेत्र लेंस की फोकस दुरी ज्ञात कीजिए।

 $\mathbf{2}$

18. क्रमश: V_p और V_d विभवों द्वारा त्विरत किसी प्रोटॉन और किसी ड्यूटेरोन से संबद्ध दे-ब्रोग्ली तरंगदैर्ध्यों के अनुपात, $\left(\frac{\lambda_p}{\lambda_d}\right)$ का मान $\frac{1}{2}$ है । $\frac{V_p}{V_d}$ ज्ञात कीजिए ।

2

19. कोई प्रकाश किरण अपवर्तनांक μ के समबाहु काँच के प्रिज्म के फलक पर अभिलम्बवत् आपतन करती है। जब इस प्रिज्म को किसी पारदर्शी माध्यम में पूर्णतः डुबोया जाता है तो यह प्रेक्षण किया जाता है कि निर्गत किरण संलग्न फलक को ठीक-ठीक स्पर्श करती है। इस माध्यम का अपवर्तनांक ज्ञात कीजिए।

2

20. वह ताप ज्ञात कीजिए जिस पर किसी चालक के प्रतिरोध में उसके $27 \, ^{\circ}\mathrm{C}$ पर प्रतिरोध के सापेक्ष 25% की वृद्धि हो जाती है। चालक का प्रतिरोध ताप गुणांक $2.0 \times 10^{-4} \, ^{\circ}\mathrm{C}^{-1}$.

2

21. किसी p-n संधि डायोड का (i) अग्रदिशिक बायसन और (ii) पश्चिदशिक बायसन में परिपथ आरेख खींचिए । इन दोनों प्रकरणों में I-V अभिलाक्षणिक भी खींचिए ।

2

2155/4/3

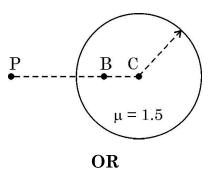


2

2

2

17. (a) An air bubble is trapped at point B (CB = 20 cm) in a glass sphere of radius 40 cm and refractive index 1.5 as shown in figure. Find the nature and position of the image of the bubble as seen by an observer at point P.



- (b) In normal adjustment, for a refracting telescope, the distance between objective and eye piece lens is 1.00 m. If the magnifying power of the telescope is 19, find the focal length of the objective and the eyepiece lens.
- 18. The ratio of de Broglie wavelengths of a proton and a deuteron accelerated by potential V_p and V_d respectively, $\left(\frac{\lambda_p}{\lambda_d}\right)$ is $\frac{1}{2}$. Find $\frac{V_p}{V_d}$.
- 19. A ray of light is incident normally on one face of an equilateral glass prism of refractive index μ. When the prism is completely immersed in a transparent medium, it is observed that the emergent ray just grazes the adjacent face. Find the refractive index of the medium.
- 20. Find the temperature at which the resistance of a conductor increases by 25% of its value at 27 °C. The temperature coefficient of resistance of the conductor is 2.0×10^{-4} °C⁻¹.
- 21. Draw the circuit diagram of a p-n junction diode in (i) forward biasing and (ii) reverse biasing. Also draw its I-V characteristics in the two cases.

2155/4/3 11 P.T.O.

22. (a) (i) अन्योन्य प्रेरकत्व की परिभाषा और इसका SI मात्रक लिखिए।

3

(ii) दो लंबी समाक्ष परिनालिकाओं, जिनकी लम्बाई समान l, फेरों की संख्या N_1 और N_2 तथा त्रिज्या r_1 और r_2 (> r_1) हैं, के बीच अन्योन्य प्रेरकत्व के लिए व्यंजक व्युत्पन्न कीजिए ।

अथवा

(b) लौह चुम्बकीय पदार्थ किन्हें कहते हैं ? चुम्बकीय डोमेन की संकल्पना का उपयोग करके उपयुक्त आरेख की सहायता से लौह चुम्बकत्व की व्याख्या कीजिए।

3

23. समान आवेश घनत्व σ से आवेशित दो गोलीय चालक खोल A और B जिनकी त्रिज्याएँ क्रमश: R और 2R हैं, एक-दूसरे से अत्यधिक दूरी पर रखे हैं। इन खोलों को किसी तार से संयोजित किया गया है। खोल A के अंतिम विभव के लिए व्यंजक प्राप्त कीजिए।

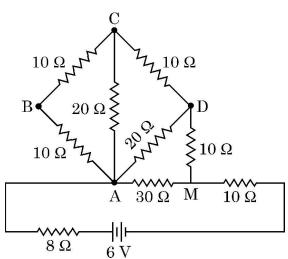
3

24. गाइगर मार्शडेन प्रयोग में प्रकीर्णन कोण (θ) के साथ संसूचित प्रकीर्णित कणों (N) के विचरण को दर्शान के लिए ग्राफ खींचिए । इस ग्राफ द्वारा आप जिन दो निष्कर्षों को निकाल सकते हैं, उन्हें लिखिए । इस प्रयोग में उपगमन की निकटतम दरी के लिए व्यंजक प्राप्त कीजिए ।

3

- 25. दिए गए नेटवर्क में परिकलित कीजिए:
 - (i) बिन्दु A और M के बीच प्रभावी प्रतिरोध, तथा
 - (ii) बैटरी द्वारा आपूर्त शक्ति

3



2155/4/3



SECTION - C

 $7 \times 3 = 21$

22. (a) (i) Define mutual inductance. Write its SI unit.

3

(ii) Derive an expression for the mutual inductance of a system of two long coaxial solenoids of same length l, having turns N_1 and N_2 and of radii r_1 and r_2 (> r_1).

OR

(b) What are ferromagnetic materials? Explain ferromagnetism with the help of suitable diagrams, using the concept of magnetic domain.

3

23. Two conducting spherical shells A and B of radii R and 2R are kept far apart and charged to the same charge density σ. They are connected by a wire. Obtain an expression for final potential of shell A.

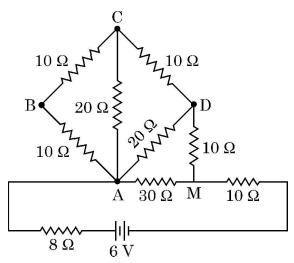
3

24. Draw the graph showing variation of scattered particles detected (N) with the scattering angle (θ) in Geiger-Marsden experiment. Write two conclusions that you can draw from this graph. Obtain the expression for the distance of closest approach in this experiment.

3

- 25. In the given network, calculate:
 - (i) effective resistance between points A and M, and
 - (ii) power supplied by the battery.

3

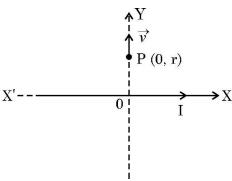


13

2155/4/3

P.T.O.

26. कोई अनन्त सीधा चालक, जिससे धारा I प्रवाहित हो रही है X'X के अनुदिश रखा है। बिन्दु $P(0, \mathbf{r})$ पर कोई आवेश q आरेख में दर्शाए अनुसार किसी वेग $\overrightarrow{v} = v_0 \hat{j}$ से गित प्रारम्भ कर देता है। आवेश द्वारा प्रारम्भ में अनुभव किए जाने वाले बल का परिमाण और दिशा ज्ञात कीजिए।



- 27. कारण सहित निम्नलिखित की व्याख्या कीजिए:
 - (i) विद्युतचुम्बकीय तरंगों की द्रव्य से अन्योन्यक्रिया करने की अपनी विधा अत्यधिक भिन्न होती हैं।
 - (ii) माइक्रोवेव अवन द्वारा गर्म किए जाने वाले खाद्य पदार्थों में जल होना चाहिए।
 - (iii) वेल्डिंग करने वाले वेल्डिंग करते समय अपने चेहरे पर काँच लगा मुखौटा पहनते हैं।
- 28. (a) नाभिकीय विखण्डन और नाभिकीय संलयन के बीच विभेदन कीजिए।
 - (b) $_{94}{\rm Pu^{239}}$ के विखण्डन गुणों और $_{92}{\rm U^{235}}$ के विखण्डन-गुणों में अत्यधिक समानता है । यदि शुद्ध $_{94}{\rm Pu^{239}}$ के 1 g के सभी परमाणुओं का विखण्डन हो जाए, तो कितनी ऊर्जा (MeV में) मुक्त होगी ? प्रति विखण्डन मुक्त औसत ऊर्जा 180 MeV है ।

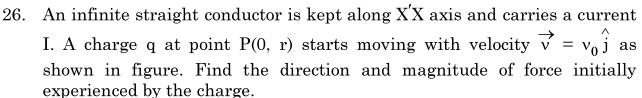
खण्ड – घ
$$2 \times 4 = 8$$

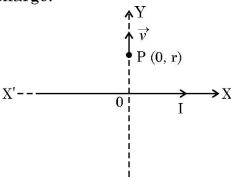
नोट: प्रश्न संख्या 29 से 30 केस आधारित प्रश्न हैं। नीचे दिए गए अनुच्छेद का अध्ययन करके प्रश्नों के उत्तर दीजिए।

29. Ge या Si जैसे शुद्ध अर्धचालकों का जब किसी उचित अपद्रव्य की अल्प मात्रा से मादन किया जाता है तो वह अपद्रव्यी अर्धचालक बन जाते हैं । तापीय साम्य में इनमें इलेक्ट्रॉन और विवर सांद्रता नैज आवेश वाहकों की सांद्रता से संबंधित होती है । उचित अपद्रव्य से भारित करने पर कोई p-प्रकार अथवा n-प्रकार का अर्धचालक p-n संधि में परिवर्तित किया जा सकता है । किसी p-n संधि के निर्माण में दो प्रक्रियाएँ विसरण और अपवाह होती हैं । कोई अर्धचालक डायोड मूल रूप से कोई p-n संधि ही होता है जिसके दो सिरों पर बाह्य वोल्टता के अनुप्रयोग के लिए धातु-संस्पर्श प्रदान किए जाते हैं । अग्र दिशिक बायसित होने पर कोई p-n संधि धारा को केवल एक ही दिशा में प्रवाहित होने देती है । इसी गुण के कारण किसी डायोड का उपयोग विस्तृत रूप में, अर्ध तरंग अथवा पूर्ण तरंग अभिविन्यासों में प्रत्यावर्ती (ac) वोल्टताओं के दिष्टकरण के लिए किया जाता है ।

2155/4/3

3





- 27. Explain the following giving reasons:
 - (i) 'Electromagnetic waves differ considerably in their mode of interaction with matter'.
 - (ii) 'Food items to be heated in microwave oven must contain water'.
 - (iii) 'Welders wear face mask with glasses during welding'.

3

28. (a) Differentiate between nuclear fission and fusion.

3

(b) The fission properties of $_{94}\mathrm{Pu^{239}}$ are very similar to those of $_{92}\mathrm{U^{235}}$. How much energy (in MeV), is released if all the atoms in 1 g of pure $_{94}\mathrm{Pu^{239}}$ undergo fission? The average energy released per fission is 180 MeV.

SECTION - D

 $2 \times 4 = 8$

Note: Questions number **29** to **30** are Case Study based questions. Read the following paragraph and answer the questions that follow.

29. A pure semiconductor like Ge or Si, when doped with a small amount of suitable impurity, becomes an extrinsic semiconductor. In thermal equilibrium, the electron and hole concentration in it are related to the charge carriers. of intrinsic A p-type or semiconductor can be converted into a p-n junction by doping it with suitable impurity. Two processes, diffusion and drift take place during formation of a p-n junction. A semiconductor diode is basically a p-n junction with metallic contacts provided at the ends for the application of an external voltage. A p-n junction diode allows currents to pass only in one direction when it is forward biased. Due to this property, a diode is widely used to rectify alternating voltages, in half-wave or full wave configuration. $4 \times 1 = 4$

2155/4/3 15 P.T.O.



- (i) जब Ge का मादन पंचसंयोजक अपद्रव्य के साथ किया जाता है, तो अपिमश्रक से दुर्बल-बंध से जुड़े इलेक्ट्रॉन को मुक्त कराने के लिए आवश्यक ऊर्जा होती है लगभग
 - (A) 0.001 eV

(B) 0.01 eV

(C) 0.72 eV

(D) 1.1 eV

- (ii) किसी दिए ताप पर किसी अर्धचालक में नैज आवेश वाहकों की संख्या $2.0 \times 10^{10} \ \mathrm{cm}^{-3}$ है। इसका मादन पंचसंयोजक अपद्रव्यी परमाणुओं से किया गया है। इसके परिणामस्वरूप इसमें विवरों (होलों) की संख्या $8 \times 10^3 \ \mathrm{cm}^{-3}$ हो जाती है। इस अर्धचालक में इलेक्ट्रॉनों की संख्या है
 - (A) $2 \times 10^{24} \text{ m}^{-3}$

(B) $4 \times 10^{23} \text{ m}^{-3}$

(C) $1 \times 10^{22} \text{ m}^{-3}$

(D) $5 \times 10^{22} \text{ m}^{-3}$

- (iii) (a) किसी p-n संधि के बनते समय
 - (A) इलेक्ट्रॉनों का p-क्षेत्र से n-क्षेत्र की ओर विसरण होता है तथा होलों का n-क्षेत्र से p-क्षेत्र की ओर विसरण होता है।
 - (B) इलेक्ट्रॉन और होल दोनों का ही n-क्षेत्र से p-क्षेत्र की ओर विसरण होता है।
 - (C) इलेक्ट्रॉनों का n-क्षेत्र से p-क्षेत्र की ओर विसरण होता है तथा होलों का p-क्षेत्र से n-क्षेत्र की ओर विसरण होता है।
 - (D) इलेक्ट्रॉनों और होल दोनों का ही p-क्षेत्र से n-क्षेत्र की ओर विसरण होता है।

अथवा

- (iii) (b) किसी p-n संधि के बनते समय आरम्भ में
 - (A) विसरण धारा बृहत् तथा अपवाह धारा लघु होती है।
 - (B) विसरण धारा लघु तथा अपवाह धारा बृहत् होती है।
 - (C) विसरण धारा तथा अपवाह धारा दोनों हीं बृहत होती हैं।
 - (D) विसरण धारा तथा अपवाह धारा दोनों हीं लघु होती हैं।
- (iv) किसी ac वोल्टता $V=0.5 \sin{(100~\pi t)}$ वोल्ट को बारी-बारी से किसी अर्ध तरंग दिष्टकारी तथा पूर्ण तरंग दिष्टकारी के सिरों से संयोजित किया गया है । इनके सिरों पर निर्गत वोल्टता की आवृत्ति क्रमशः होगी
 - (A) 25 Hz, 50 Hz

(B) 25 Hz, 100 Hz

(C) 50 Hz, 50 Hz

- (D) 50 Hz, 100 Hz
- 30. कोई लेंस दो पृष्ठों से घिरा ऐसा पारदर्शी प्रकाशिक माध्यम होता है जिसके दोनों पृष्ठों में कम से कम एक गोलीय होना चाहिए। किसी एकल गोलीय पृष्ठ द्वारा निर्मित प्रतिबिम्ब के लिए सूत्र का उपयोग किसी लेंस के दो पृष्ठों पर क्रमिक रूप में करके पतले लेंसों के लिए लेंस सूत्र जिसे लेंस मेकर सूत्र और इस प्रकार मूल लेंस सूत्र प्राप्त किया जाता है। किसी लेंस की फोकस दूरी (अथवा क्षमता) लेंस के दोनों पृष्ठों की त्रिज्याओं तथा प्रतिवेश के सापेक्ष लेंस के पदार्थ के अपवर्तनांक पर निर्भर करता है। किसी पदार्थ का अपवर्तनांक उपयोग किए गए प्रकाश की तरंगदैध्य पर निर्भर करता है। लेंसों का संयोजन वांछित क्षमता और आवर्धन के अपसारी और अभिसारी लेंसों को प्राप्त करने में हमारी सहायता करता है। $4 \times 1 = 4$

2155/4/3

- (i) When Ge is doped with pentavalent impurity, the energy required to free the weakly bound electron from the dopant is about
 - (A) 0.001 eV

(B) 0.01 eV

(C) 0.72 eV

(D) 1.1 eV

- (ii) At a given temperature, the number of intrinsic charge carriers in a semiconductor is 2.0×10^{10} cm⁻³. It is doped with pentavalent impurity atoms. As a result, the number of holes in it becomes 8×10^3 cm⁻³. The number of electrons in the semiconductor is
 - (A) $2 \times 10^{24} \text{ m}^{-3}$

(B) $4 \times 10^{23} \text{ m}^{-3}$

(C) $1 \times 10^{22} \text{ m}^{-3}$

(D) $5 \times 10^{22} \text{ m}^{-3}$

- (iii) (a) During the formation of a p-n junction
 - (A) electrons diffuse from p-region into n-region and holes diffuse from n-region into p-region.
 - (B) both electrons and holes diffuse from n-region into p-region.
 - (C) electrons diffuse from n-region into p-region and holes diffuse from p-region into n-region.
 - (D) both electrons and holes diffuse from p-region into n-region.

OR

- (iii) (b) Initially during the formation of a p-n junction
 - (A) diffusion current is large and drift current is small.
 - (B) diffusion current is small and drift current is large.
 - (C) both the diffusion and the drift currents are large.
 - (D) both the diffusion and the drift currents are small.
- (iv) An ac voltage $V = 0.5 \sin (100 \pi t)$ volt is applied, in turn, across a half-wave rectifier and a full-wave rectifier. The frequency of the output voltage across them respectively will be

(A) 25 Hz, 50 Hz

(B) 25 Hz, 100 Hz

(C) 50 Hz, 50 Hz

(D) 50 Hz, 100 Hz

30. A lens is a transparent optical medium bounded by two surfaces; at least one of which should be spherical. Applying the formula of image formation by a single spherical surface successively at the two surfaces of a thin lens, a formula known as lens maker's formula and hence the basic lens formula can be obtained. The focal length (or power) of a lens depends on the radii of its surfaces and the refractive index of its material with respect to the surrounding medium. The refractive index of a material depends on the wavelength of light used. Combination of lenses helps us to obtain diverging or converging lenses of desired power and magnification. $4 \times 1 = 4$

2155/4/3 17 P.T.O.



- (i) 20 cm फोकस दूरी का कोई पतला अपसारी लेंस 15 cm फोकस दूरी के पतले अभिसारी लेंस के सम्पर्क में समाक्ष रखा है। इस संयोजन की क्षमता है –
 - (A) $\frac{-5}{6}$ D

(B) $\frac{-5}{3}$ D

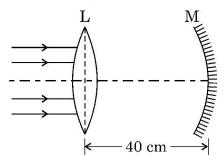
(C) $\frac{4}{3}$ D

- (D) $\frac{3}{2}$ D
- (ii) किसी उत्तल लेंस के दो पृष्ठों की वक्रता त्रिज्या R और 2R हैं । यदि इस लेंस की फोकस दूरी $\left(\frac{4}{3}\right)R$ है, तो लेंस के पदार्थ का अपवर्तनांक है :
 - (A) $\frac{5}{3}$

(B) $\frac{4}{3}$

(C) $\frac{3}{2}$

- (D) $\frac{7}{5}$
- (iii) किसी समतलोत्तल लेंस की फोकस दूरी
 - (A) पानी में डुबोने पर बढ़ जाती है।
 - (B) आपितत प्रकाश की तरंगदैर्ध्य में कमी होने पर बढ़ जाती है।
 - (C) इसके पृष्ठों की वक्रता त्रिज्या में कमी होने पर बढ़ जाती है।
 - (D) मुख्य अक्ष के अनुदिश दो सर्वसम भागों में काटे जाने पर घट जाती है।
- (iv) (a) आरेख में दर्शाए अनुसार 10 cm फोकस दूरी का कोई उत्तल पतला लेंस L और 15 cm फोकस दूरी का कोई अवतल दर्पण M एक-दूसरे से 40 cm की दूरी पर समाक्ष स्थित हैं। मुख्य अक्ष से समान्तर कोई प्रकाश पुन्ज लेंस पर आपतन करता है। अंतिम प्रतिबिम्ब लेंस के सापेक्ष कहाँ और कितनी दूरी पर बनेगा?



- (A) 10 cm, लेंस के बायीं ओर
- (B) 10 cm, लेंस के दायीं ओर
- (C) 20 cm, लेंस के बायीं ओर
- (D) 20 cm, लेंस के दायीं ओर

अथवा

2155/4/3

- (i) A thin converging lens of focal length 20 cm and a thin diverging lens of focal length 15 cm are placed coaxially in contact. The power of the combination is
 - (A) $\frac{-5}{6}$ D

(B) $\frac{-5}{3}$ D

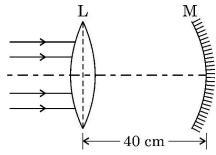
(C) $\frac{4}{3}$ D

- (D) $\frac{3}{2}$ D
- (ii) The radii of curvature of two surfaces of a convex lens are R and 2R. If the focal length of this lens is $\left(\frac{4}{3}\right)R$, the refractive index of the material of the lens is:
 - (A) $\frac{5}{3}$

(B) $\frac{4}{3}$

(C) $\frac{3}{2}$

- (D) $\frac{7}{5}$
- (iii) The focal length of an equiconvex lens
 - (A) increases when the lens is dipped in water.
 - (B) increases when the wavelength of incident light decreases.
 - (C) increases with decrease in radius of curvature of its surface.
 - (D) decreases when the lens is cut into two identical parts along its principal axis.
- (iv) (a) A thin convex lens L of focal length 10 cm and a concave mirror M of focal length 15 cm are placed coaxially 40 cm apart as shown in figure. A beam of light coming parallel to the principal axis is incident on the lens. The final image will be formed at a distance of



- (A) 10 cm, left of lens
- (B) 10 cm, right of lens
- (C) 20 cm, left of lens
- (D) 20 cm, right of lens

OR

- $16~{
 m cm}$ फोकस दूरी के किसी उत्तल लेंस ${
 m L_1}$ पर कोई प्रकाश पुन्ज, जो लेंस के मुख्य अक्ष (iv) (b) के समान्तर है, आपतन कर रहा है। लेंस ${
 m L_1}$ के समाक्ष कोई अन्य उत्तल लेंस ${
 m L_2}$ जिसकी फोकस दुरी $12~\mathrm{cm}$ है, $40~\mathrm{cm}$ दुरी पर स्थित है। अंतिम प्रतिबिम्ब की प्रकृति और लेंस ${\bf L}_2$ से दूरी होगी क्रमश:
 - (A) वास्तविक, 24 cm
- (B) आभासी, 12 cm
- (C) वास्तविक, 32 cm
- (D) आभासी, 18 cm

खण्ड – ङ

 $3 \times 5 = 15$

5

- किसी समान्तर पट्टिका संधारित्र जिसकी पट्टिकाओं के बीच पृथकन d तथा पट्टिकाओं का 31. (a) (i) क्षेत्रफल A है, की पट्टिकाओं के बीच परावैद्युतांक 'K' और मोटाई 't' का कोई गुटका रखा गया है। इस संधारित्र की धारिता के लिए व्यंजक प्राप्त कीजिए।
 - दो विभिन्न धारिताओं के संधारित्रों को पहले (1) श्रेणी में और फिर (2) पार्श्व में किसी 100~
 m V(ii) के dc स्रोत से संयोजित किया गया है। यदि इन दोनों प्रकरणों में संयोजनों में संचित कुल ऊर्जा क्रमशः 40 mJ और 250 mJ हैं, तो इन संधारित्रों की धारिताएँ ज्ञात कीजिए।

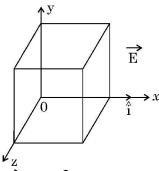
अथवा

- गाउस नियम का उपयोग करके यह दर्शाइए कि किसी एकसमान आवेशित अनन्त समतल (b) (i) चादर के कारण किसी बिन्दु पर विद्युत क्षेत्र $\overset{
 ightarrow}{E}=\frac{\sigma}{2\epsilon_0}\stackrel{\wedge}{n}$ से व्यक्त होता है । यहाँ प्रतीकों के अपने सामान्य अर्थ हैं।
 - (ii) किसी प्रदेश में विद्युत क्षेत्र E को इस प्रकार व्यक्त किया गया है

$$\overrightarrow{E} = (5x^2 + 2) \hat{i}$$

यहाँ ${f E}$ को ${f N}/{f C}$ तथा x को मीटरों में व्यक्त किया गया है।

इस प्रदेश में भुजा $10~\mathrm{cm}$ के किसी घन को आरेख में दर्शाए अनुसार स्थित किया गया है। परिकलित कीजिए।



- इस घन से गुजरने वाला विद्युत फ्लक्स, तथा (1)
- इस घन द्वारा परिबद्ध नेट आवेश। (2)

5

2155/4/3

- (iv) (b) A beam of light coming parallel to the principal axis of a convex lens L_1 of focal length 16 cm is incident on it. Another convex lens L_2 of focal length 12 cm is placed coaxially at a distance 40 cm from L_1 . The nature and distance of the final image from L_2 will be
 - (A) real, 24 cm

(B) virtual, 12 cm

(C) real, 32 cm

(D) virtual, 18 cm

SECTION - E

 $3 \times 5 = 15$

5

- 31. (a) (i) A dielectric slab of dielectric constant 'K' and thickness 't' is inserted between plates of a parallel plate capacitor of plate separation d and plate area A. Obtain an expression for its capacitance.
 - (ii) Two capacitors of different capacitances are connected first (1) in series and then (2) in parallel across a dc source of 100 V. If the total energy stored in the combination in the two cases are 40 mJ and 250 mJ respectively, find the capacitance of the capacitors.

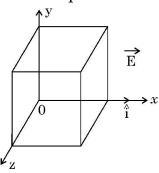
OR

- (b) (i) Using Gauss's law, show that the electric field $\stackrel{\longrightarrow}{E}$ at a point due to a uniformly charged infinite plane sheet is given by $\stackrel{\longrightarrow}{E} = \frac{\sigma}{2\epsilon_0} \stackrel{\cap}{n}$ where symbols have their usual meanings.
 - (ii) Electric field E in a region is given by

$$\overrightarrow{E} = (5x^2 + 2) \hat{i}$$

where E is in N/C and x is in meters.

A cube of side 10 cm is placed in the region as shown in figure.



Calculate (1) the electric flux through the cube, and (2) the net charge enclosed by the cube.

2155/4/3 21

5

P.T.O.

- किसी उत्तल दर्पण द्वारा किसी बिम्ब का प्रतिबिम्ब बनना दर्शाने के लिए किरण आरेख 32. (a) (i) खींचिए और इससे दर्पण समीकरण प्राप्त कीजिए।
 - प्रकाशिक यंत्रों के अभिदृश्यक और अभिनेत्र लेंस (नेत्रिका) दोनों के लिए बहुघटक लेंसों (ii) का उपयोग क्यों किया जाता है ?
 - (iii) किसी संयुक्त सूक्ष्मदर्शी द्वारा किसी लघु बिम्ब का आवर्धन 200 है। नेत्रिका की फोकस द्री 2 cm है तथा अंतिम प्रतिबिम्ब अनन्त पर बनता है । अभिदृश्यक द्वारा उत्पन्न आवर्धन ज्ञात कीजिए।

अथवा

- किसी तरंगाग्र और किसी किरण के बीच विभेदन कीजिए। (b) (i)
 - हाइगेन्स सिद्धान्त लिखिए तथा उपयुक्त आरेख का उपयोग करके परावर्तन के नियमों का सत्यापन (ii) कीजिए।
 - (iii) यंग के द्विझिरी प्रयोग में झिरियों S_1 और S_2 के बीच की दूरी $3~\mathrm{mm}$ है तथा पर्दे की झिरियों से दुरी 1.0 m है। यह प्रेक्षण किया गया है कि चौथी चमकीली फ्रिन्ज दुसरी काली फ्रिन्ज से 5 mm की दुरी पर है। उपयोग किए जाने वाले प्रकाश की तरंगदैर्ध्य ज्ञात कीजिए।
- उन कारकों का उल्लेख कीजिए जिन पर किसी LCR श्रेणी परिपथ की अनुनाद की आवृत्ति 33. (a) (i) निर्भर करती है। अनुप्रयुक्त ac स्रोत की आवृत्ति के साथ LCR श्रेणी परिपथ की प्रतिबाधा में विचरण को दर्शाने के लिए ग्राफ खींचिए।
 - उपयुक्त आरेख की सहायता से किसी उच्चायी ट्रान्सफॉर्मर की कार्यविधि की व्याख्या कीजिए। (ii)
 - किसी वास्तविक ट्रान्सफॉर्मर में ऊर्जा-क्षय के दो कारण लिखिए।

अथवा

- आरेख की सहायता से किसी ac जिनत्र की संरचना और कार्यविधि की संक्षेप में व्याख्या कीजिए। (b) (i)
 - कोई इलेक्ट्रॉन किसी प्रोटॉन की परिक्रमा त्रिज्या ${f r}$ की कक्षा में चाल ${f v}$ से कर रहा है । इस (ii) इलेक्ट्रॉन से संबद्ध चुम्बकीय आघूर्ण के लिए व्यंजक प्राप्त कीजिए। 5

22 2155/4/3

Get More Learning Materials Here:



5

5

- 32. (a) (i) Draw a ray diagram for the formation of the image of an object by a convex mirror. Hence, obtain the mirror equation.
 - (ii) Why are multi-component lenses used for both the objective and the eyepiece in optical instruments?
 - (iii) The magnification of a small object produced by a compound microscope is 200. The focal length of the eyepiece is 2 cm and the final image is formed at infinity. Find the magnification produced by the objective.

OR

- (b) (i) Differentiate between a wavefront and a ray.
 - (ii) State Huygen's principle and verify laws of reflection using suitable diagram.
 - (iii) In Young's double slit experiment, the slits S_1 and S_2 are 3 mm apart and the screen is placed 1.0 m away from the slits. It is observed that the fourth bright fringe is at a distance of 5 mm from the second dark fringe. Find the wavelength of light used.
- 33. (a) (i) Mention the factors on which the resonant frequency of a series LCR circuit depends. Plot a graph showing variation of impedance of a series LCR circuit with the frequency of the applied a.c. source.
 - (ii) With the help of a suitable diagram, explain the working of a step-up transformer.
 - (iii) Write two causes of energy loss in a real transformer.

OR

- (b) (i) With the help of a diagram, briefly explain the construction and working of ac generator.
 - (ii) An electron is revolving around a proton in an orbit of radius r with a speed v. Obtain expression for magnetic moment associated with the electron.

2155/4/3





5

5

5

2155/4/3 **221 C**

Marking Scheme Strictly Confidential (For Internal and Restricted use only) Senior School Certificate Examination, 2024

SUBJECT PHYSICS (CODE 55/4/1)

General Instructions: -

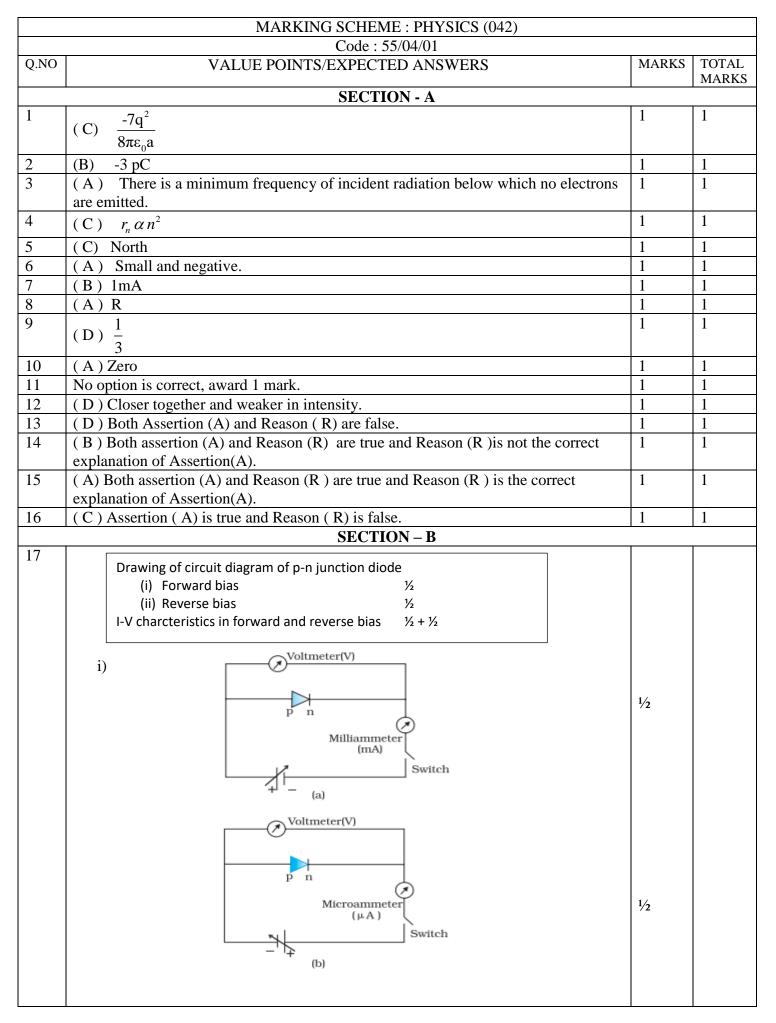
Gene	ral Instructions: -
2	You are aware that evaluation is the most important process in the actual and correct assessment of the candidates. A small mistake in evaluation may lead to serious problems which may affect the future of the candidates, education system and teaching profession. To avoid mistakes, it is requested that before starting evaluation, you must read and understand the spot evaluation guidelines carefully. "Evaluation policy is a confidential policy as it is related to the confidentiality of the examinations conducted, Evaluation done and several other aspects. Its' leakage to public in any manner could lead to derailment of the examination system and affect the life and future of millions of candidates. Sharing this policy/document to anyone, publishing in any magazine and printing in News Paper/Website etc may invite action under various rules of
	the Board and IPC."
3	Evaluation is to be done as per instructions provided in the Marking Scheme. It should not be done according to one's own interpretation or any other consideration. Marking Scheme should be strictly adhered to and religiously followed. However, while evaluating, answers which are based on latest information or knowledge and/or are innovative, they may be assessed for their correctness otherwise and due marks be awarded to them. In class-X, while evaluating two competency-based questions, please try to understand given answer and even if reply is not from marking scheme but correct competency is enumerated by the candidate, due marks should be awarded.
4	The Marking scheme carries only suggested value points for the answers
	These are in the nature of Guidelines only and do not constitute the complete answer. The students can have their own expression and if the expression is correct, the due marks should be awarded accordingly.
5	The Head-Examiner must go through the first five answer books evaluated by each evaluator on the first day, to ensure that evaluation has been carried out as per the instructions given in the Marking Scheme. If there is any variation, the same should be zero after delibration and discussion. The remaining answer books meant for evaluation shall be given only after ensuring that there is no significant variation in the marking of individual evaluators.
6	Evaluators will mark($\sqrt{\ }$) wherever answer is correct. For wrong answer CROSS 'X" be marked.
	Evaluators will not put right () while evaluating which gives an impression that answer is correct and no marks are awarded. This is most common mistake which evaluators are committing.
7	If a question has parts, please award marks on the right-hand side for each part. Marks awarded for different parts of the question should then be totaled up and written in the left-hand margin and encircled. This may be followed strictly.
8	If a question does not have any parts, marks must be awarded in the left-hand margin and

55/4/1 page 1 of 15

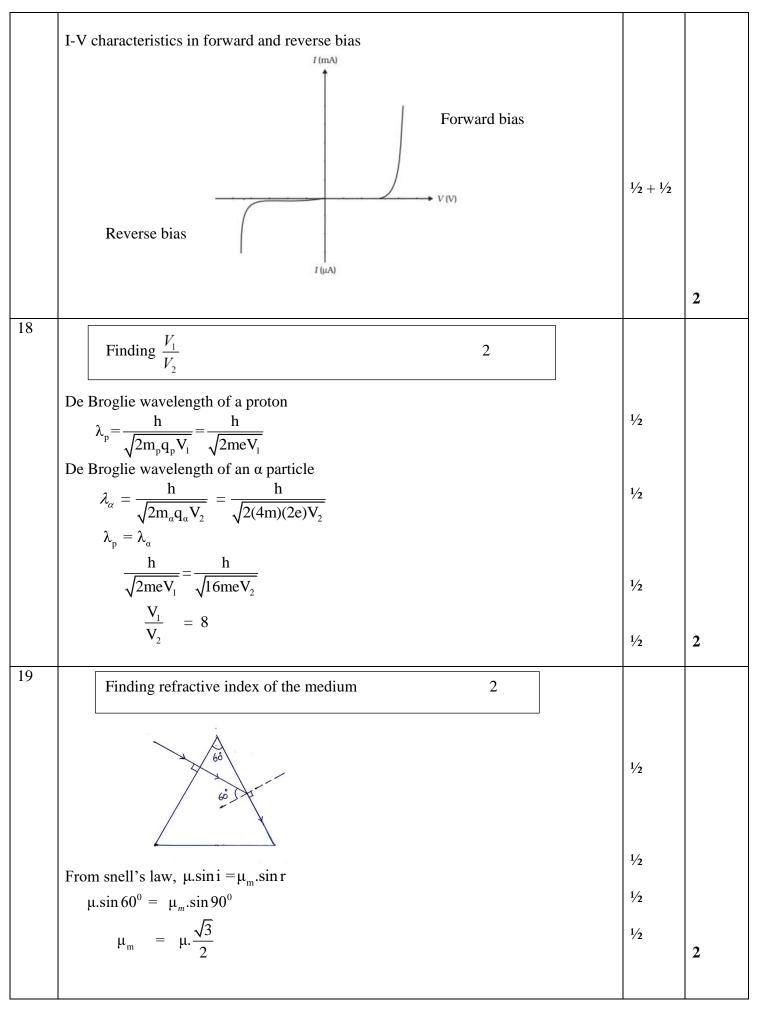




	encircled. This may also be followed strictly.
9	If a student has attempted an extra question, answer of the question deserving more marks should be retained and the other answer scored out with a note "Extra Question".
10	No marks to be deducted for the cumulative effect of an error. It should be penalized only once.
11	A full scale of marks0 to 70(example 0 to 80/70/60/50/40/30 marks as given in Question Paper) has to be used. Please do not hesitate to award full marks if the answer deserves it.
12	Every examiner has to necessarily do evaluation work for full working hours i.e., 8 hours every day and evaluate 20 answer books per day in main subjects and 25 answer books per day in other subjects (Details are given in Spot Guidelines). This is in view of the reduced syllabus and number of questions in question paper.
13	 Ensure that you do not make the following common types of errors committed by the Examiner in the past:- Leaving answer or part thereof unassessed in an answer book. Giving more marks for an answer than assigned to it. Wrong totaling of marks awarded on an answer. Wrong transfer of marks from the inside pages of the answer book to the title page. Wrong question wise totaling on the title page. Wrong totaling of marks of the two columns on the title page. Wrong grand total. Marks in words and figures not tallying/not same. Wrong transfer of marks from the answer book to online award list. Answers marked as correct, but marks not awarded. (Ensure that the right tick mark is correctly and clearly indicated. It should merely be a line. Same is with the X for incorrect answer.) Half or a part of answer marked correct and the rest as wrong, but no marks awarded.
14	While evaluating the answer books if the answer is found to be totally incorrect, it should be marked as cross (X) and awarded zero (0)Marks.
15	Any unassessed portion, non-carrying over of marks to the title page, or totaling error detected by the candidate shall damage the prestige of all the personnel engaged in the evaluation work as also of the Board. Hence, in order to uphold the prestige of all concerned, it is again reiterated that the instructions be followed meticulously and judiciously.
16	The Examiners should acquaint themselves with the guidelines given in the "Guidelines for Spot Evaluation" before starting the actual evaluation.
17	Every Examiner shall also ensure that all the answers are evaluated, marks carried over to the title page, correctly totaled and written in figures and words.
18	The candidates are entitled to obtain photocopy of the Answer Book on request on payment of the prescribed processing fee. All Examiners/Additional Head Examiners/Head Examiners are once again reminded that they must ensure that evaluation is carried out strictly as per value points for each answer as given in the Marking Scheme.



55/4/1 page 3 of 15

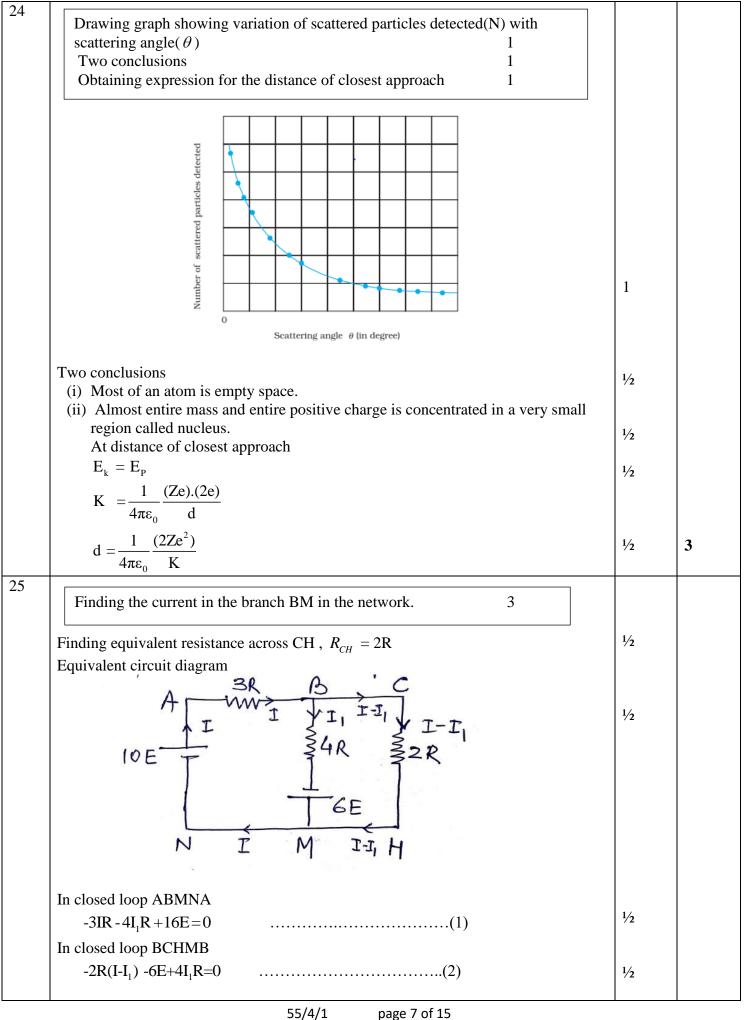


	<u>Alternatively</u>		
	$\mu = \frac{1}{\sin C}$	1	
	$\frac{\mu}{\mu_m} = \frac{1}{\sin 60^0}$	1/2	
	$\mu_m = \sin 60^\circ$		
	$\mu_m = \frac{\sqrt{3}}{2}\mu$	1/2	
20			
	Finding power consumed by two electric heaters in series combination 1½		
	Writing answer for parallel combination ½		
	$R_1 = \frac{V^2}{P_1} \& R_2 = \frac{V^2}{P_2}$	1/2	
	$R_{eq} = R_1 + R_2 = V^2 \left(\frac{1}{P_1} + \frac{1}{P_2} \right)$	1/2	
	$P_{\text{series}} = \frac{V^2}{R_{\text{eq}}}$		
	$P_{\text{series}} = \frac{V^2}{V^2 \left(\frac{1}{P_1} + \frac{1}{P_2}\right)}$		
	$\frac{1}{P_{\text{series}}} = \frac{1}{P_1} + \frac{1}{P_2}$	1/	
	$egin{array}{cccccccccccccccccccccccccccccccccccc$	1/2	
	No	1/2	2
21	(a) Finding nature and position of image 2		
	Using refraction formula at spherical surface from denser to rarer medium		
	n_1 = refractive index of rarer medium		
	n_2 = refractive index of denser medium	1/2	
	$\frac{n_1}{v} - \frac{n_2}{u} = \frac{n_1 - n_2}{R}$		
	v u R $u = -20 \text{ cm}$, R= -40 cm , $n_1 = 1$, $n_2 = 1.5$	1/2	
		/2	
	$\frac{1}{v} - \frac{1.5}{(-20)} = \frac{1-1.5}{(-40)}$		
	v = -16 cm	1/2	2
	Nature of image is virtual.	1/2	4
	OR		
	(b) Finding the focal lengths of the objective and eyepiece 2		
	Distance between objective and eyepiece	1/2	
	fo + fe = 1.00 m = 100 cm	72	
	Magnifying power		
	$ m = \frac{\text{fo}}{\text{fe}} = 19$	1/2	
		ĺ	i

55/4/1

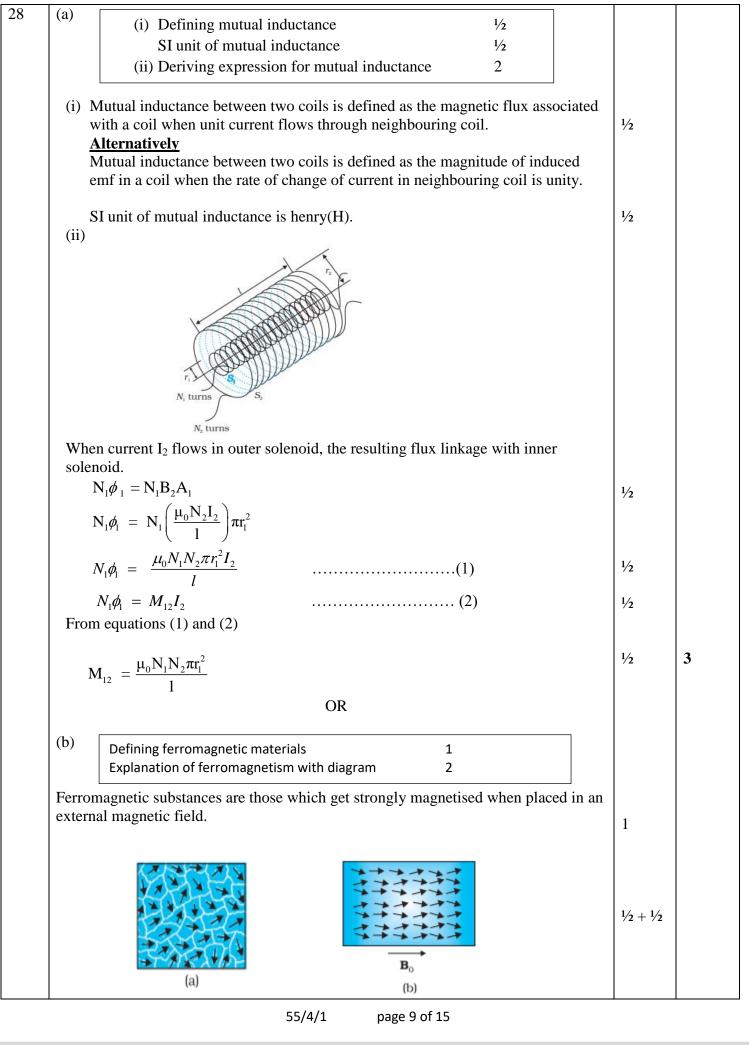
page 5 of 15

	On solving		
	fo = 95 cm = 0.95 m	1/2	
	fe = 5 cm = 0.05 m	1/2	
	SECTION - C	1 -	1
22			
	(a) Difference between nuclear fission and fusion (1)		
	(b) Calculating energy released in fission (2)		
	(a) In nuclear fission, a heavy nucleus splits into two or more lighter nuclei and		
	energy is released.	1/2	
	In nuclear fusion, lighter nuclei combine together a form a heavy nucleus and	/ =	
	larger amount of energy is released.	1/2	
	(b) Number of atoms in 1 g of ₉₄ Pu ²³⁹		
	74		
	6.023×10^{23}		
	$=\frac{6.023\times10^{23}}{239}$		
	$= 2.5 \times 10^{21}$	1	
		1	
	Energy released in fission of 1 g of $_{94}Pu^{239}$,		
	$E = 180 \text{MeV} \times 2.5 \times 10^{21}$		
	$E = 4.5 \times 10^{23} \text{ MeV}$	1	3
23			
	Calculating work done in taking a unit charge from		
	(i) (5m, 0) to (10m, 0) 2 (ii) (5m, 0) to (5m, 10m) 1		
	(11) (3111, 0) to (3111, 10111)		
	(i)		
	x ₂	1/2	
	$\Delta V = -\int E dx$		
	x ₁ 10		
	$\Delta V = -\int_{5}^{10} (10x+4) dx = -\left[\frac{10x^2}{2} + 4x \right]_{5}^{10}$		
	$\begin{bmatrix} \mathbf{J} \\ 5 \end{bmatrix}$	1/2	
	= -395 V		
	$W = q\Delta V = -395 \times 1$	1/2	
	= -395 J	1/2	
	(ii)		
	$\Delta V = -\int_{1}^{x_{2}} E dx$		
	x ₁		
	$\Delta V = -\int_{5}^{3} (10x+4) dx = 0$	1/2	
	5	4./	
	$W = q.\Delta V = 0$	1/2	3
	<u>Alternatively</u>		
	If a student writes, displacement is perpendicular to electric field then		
	$\Delta V = 0$	1/2	
	$W = q.\Delta V = 0$	1/2	
	Award full credit for part (ii)		
	55/4/1 page 6 of 15		



	On solving equations (1) and (2)		
	$I_1 = \frac{25E}{13R}$	1	3
26	Finding value of current in a long straight wire 2 ½		
	Finding direction of current in a long straight wire ½		
	Magnetic field due to circular current loop at its centre O.		
	$\mathbf{B}_1 = \frac{\mu_0 \mathbf{I}_1}{2\mathbf{r}}$	1/2	
	$=\frac{\mu_0\times 1}{2\times 0.1}$		
	$= 5\mu_0 T$	1/2	
	The magnetic field B_1 is perpendicular to plane of loop and directed inwards.		
	Magnetic field due to long current carrying straight wire at O.		
	$\mathbf{B}_2 = \frac{\mu_0 \mathbf{I}_2}{2\pi \mathbf{r}}$	1/2	
	$\mathbf{B}_2 = \frac{\mu_0 \mathbf{I}_2}{2\pi \times 0.2} \mathbf{T}$		
	For net magnetic field at O to be zero, B_1 should be equal and opposite to B_2 .		
	$5\mu_0 = \frac{\mu_0 I_2}{0.4\pi}$	1/2	
	$I_2 = 2\pi A$	1/2	
	= 6.28 A		
	Direction of current in the straight wire is along +ve x axis.	1/2	3
	Alternatively Net magnetic field at O is zero.		
		1/2	
	$\mathbf{B}_{\mathrm{loop}} = \mathbf{B}_{\mathrm{wire}}$		
	$rac{\mu_0 ext{I}_1}{2 ext{r}_1} \; = rac{\mu_0 ext{I}_2}{2\pi ext{r}_2}$	1	
	$\frac{\mu_0 \times 1}{\mu_0 \times 1} = \frac{\mu_0 I_2}{\mu_0 I_2}$	1/2	
	2×0.1 $2\pi\times0.2$	1/2	
	$I_2 = 2\pi A$		
	= 6.28 A Direction of current is along + x-axis.	1/2	
27			
	Naming the electromagnetic waves 1 ½ Writing range of electromagnetic waves 1 ½		
	Electromagnetic waves wavelength range		
	(i) Radio waves > 0.1 m	1/2 + 1/2	
	(ii) X- rays $1 \text{nm} - 10^{-3} \text{ nm}$	1/2 + 1/2	
	(iii) Infrared waves 1mm-700nm	1/2 + 1/2	3
·	55/4/1 page 8 of 15	<u> </u>	1

55/4/1 page 8 of 15



	In absence of external magnetic field, domains are randomly oriented and it exhibits weak magnetisation. In the presence of external magnetic field domains orient themselves in the direction of magnetic field and it exhibits strong magnetisation.	1/2	
29	SECTION - D		
29	 (i) (B) 0.01 eV (ii) (D) 5×10²² m⁻³ (iii) (a) (C) Electrons diffuse from n-region into p-region and holes diffuse from p-region to n-region. OR (b) (A) Diffusion current is large and drift current is small. 	1 1 1	
	(iv) (D) 50 Hz, 100 Hz.	1	4
30	(i) (B) $\frac{-5}{3}D$ (ii) (C) $\frac{3}{2}$	1	
	(iii) (A) increases when a lens is dipped in water. (iv) (a) (B) 10 cm, right from lens. OR	1 1	4
	(b) (A) real, 24 cm SECTION - E		
31	a) i) Drawing of ray diagram Obtaining mirror equation ii) Reason for using multi-component lenses iii) Finding magnification produced by the objective 1	1	
	For paraxial rays MP can be considered to be a straight line perpendicular to CP, Therefore right angled triangles \overrightarrow{ABF} and MPF are similar $\frac{\overrightarrow{BA}}{\overrightarrow{PM}} = \frac{\overrightarrow{BF}}{\overrightarrow{FP}}$ B'A' B'F		
	Or $\frac{BA}{BA} = \frac{BF}{FP}$ (: PM = AB)(1) Since \angle APB = \angle APB , the right angled triangles APB and ABP are also similar	1/2	

T			
	Therefore, $\frac{B'A'}{BA} = \frac{B'P}{BP}$ (2)	1/2	
	BA BP Comparing eq (1) and (2), we get	, _	
	$\frac{B'F}{FP} = \frac{B'P}{BP}$		
	FP BP		
	$\frac{PF-PB'}{B} = \frac{B'P}{B'}$		
	$\frac{2}{\text{FP}} = \frac{2}{\text{BP}}$		
	Using sign convention		
	PF = f, PB' = +v, $PB = -u$	1/2	
	. 1 1 1	1/2	
	on solving $\frac{1}{v} + \frac{1}{u} = \frac{1}{f}$, -	
	ii) To improve image quality by minimizing various optical aberrations in lenses.	1	
		1	
	iii) Magnification produced by compound microscope		
	$m = m_o \times m_e$	1/2	
	$m_{o} = \frac{m}{m_{e}} = \frac{m}{\left \frac{D}{fe}\right }$		
	$\mathbf{m}_{\mathrm{e}} \mathbf{m}_{\mathrm{e}} \mathbf{\underline{D}} $		
	fe		
	$m - \frac{200}{100} = 16$	1/2	5
	$m_o = \frac{200}{25} = 16$	/2	
	2		
	OR		
	(b) D:gg		
	1) Difference between a wavefront and a ray		
	ii) Statement of Huygens' principle 1		
	Verification of the law of reflection 1½		
	iii) Finding wavelength of light 1 ½		
	i) Wavefront is a surface of constant phase.	1/2	
	Alternatively Locus of points, which oscillate in phase	/2	
	Ray - The straight line path along which light travels (or energy propagates).	1/2	
	<u>Alternatively –</u> Ray is normal to wave front.		
	ii) <u>Huygens' Principle</u> Each point of the wave front is the source of secondary		
	disturbance and the wavelets emanating from the points spread out in all		
	directions with speed of wave. The wavelets emanating from wave front are usually referred to as secondary wavelets. A common tangent to all these spheres	1	
	gives the new position of the wave front at a later time.		
	Incident		
	wavefront		
	F. A. Dodouted		
	B Reflected wavefront	1	
	\\\\ \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\		
	$M \longrightarrow A \longrightarrow C \longrightarrow C \longrightarrow N$		
	Triangles EAC and BAC are congruent therefore $\angle i = \angle r$	1/2	
	Thangles EAC and DAC are congruent dieterore $\angle l = \angle l$		
	55/4/1 page 11 of 15		

	iii) Position of 4 th bright fringe		
	$x_{4(bright)} = 4 \frac{D\lambda}{d}$	1/2	
	l a		
	Position of 2 nd dark fringe	1/2	
	$x_{2(dark)} = \frac{3}{2} \frac{D\lambda}{d}$, 2	
	$x_{4(bright)} - x_{2(dark)} = 5mm$		
	$4\frac{\mathrm{D}\lambda}{\mathrm{d}} - \frac{3}{2}\frac{\mathrm{D}\lambda}{\mathrm{d}} = 5 \times 10^{-3}$		
	$\lambda=6\times10^{-6}$ m	1/2	
32	<i>κ</i> −0∧10 m		
32	(i) Obtaining expression for capacitance 3		
	(ii) Finding capacitance of capacitors 2		
	2) (;)		
	a) (i) Electric field in air between plates		
		1/2	
	$E_0 = \frac{\sigma}{\varepsilon_0}$ Electric field inside the dielectric		
	Electric field inside the dielectric		
	$E = \frac{\sigma}{\varepsilon_0 K} \qquad \qquad \underbrace{\leftarrow t \rightarrow}_{\leftarrow t \rightarrow} \qquad \underbrace{\leftarrow}_{\leftarrow t \rightarrow}$	1/2	
	Potential difference between the plates	1/	
	$V=E_0(d-t)+Et$	1/2	
	$V = \frac{\sigma}{\varepsilon_0} \left[d - t + \frac{t}{K} \right]$		
	$V = \frac{q}{A\varepsilon_0} \left[d - t + \frac{t}{K} \right]$	1/2	
	$A\varepsilon_0 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$	/2	
	$C = \frac{q}{V}$	1/2	
	$C = \frac{q}{V}$ $C = \frac{A\epsilon_0}{d-t + \frac{t}{K}}$		
	$d-t+\frac{t}{K}$		
	$C = \frac{A\varepsilon_0}{d - t\left(1 - \frac{1}{K}\right)}$	1/2	
	$c = \frac{1}{d-t\left(1-\frac{1}{2}\right)}$,2	
	(K)		
	ii) Total energy stored in series combination		
	$\frac{1}{2} \left(\frac{C_1 C_2}{C_1 + C_2} \right) V^2 = 40 \times 10^{-3} \text{ J} $ (1)	1/2	
	Energy stored in parallel combination		
	$\frac{1}{2} (C_1 + C_2) V^2 = 250 \times 10^{-3} J(2)$	1/2	
	Substituting value of V=100 V in eq (1) and (2), on solving		
	$C_1 = 4 \times 10^{-5} \text{F or } 40 \mu\text{F}$	1/2	
	$C_2 = 1 \times 10^{-5} \text{ F or } 10 \mu\text{F}$	1/2	5
<u> </u>	55/4/1 page 12 of 15	1	I

b)

- i) Showing electric field at a point due to a uniformly charged infinite plane sheet
- ii) Calculating
- (1) electric flux through the cube

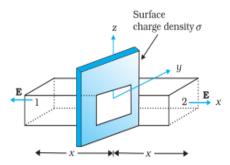
3

1

1

(2) charge enclosed by cube

(i)



$$\oint \vec{E}.d\vec{s} = \int_{1} \vec{E}.d\vec{s} + \int_{2} \vec{E}.d\vec{s}$$

$$= 2EA$$

From Gauss's law

$$\label{eq:energy} \begin{split} \oint \vec{E}.d\vec{s} &= \frac{q}{\epsilon_0} \\ 2EA &= \frac{\sigma A}{\epsilon_0} \end{split}$$

$$\frac{\epsilon_0}{\epsilon_0}$$

$$E = \frac{\sigma}{2\epsilon_0}$$

Vectorially $\vec{E} = \frac{\sigma}{2\epsilon_0} \hat{n}$

Electric field is normally outward of the sheet.

(1) Electric flux through the cube

$$\begin{split} \phi &= \phi_L + \phi_R \\ \phi &= \int \vec{E}_L . d\vec{s} + \int \vec{E}_R . d\vec{s} \\ &= -2 \times 100 \times 10^{-4} + [5 \times (10 \times 10^{-2})^2 + 2] \times 100 \times 10^{-4} \end{split}$$

$$\phi = 5 \times 10^{-4} \text{ Nm}^2 \text{C}^{-1}$$

1/2

1

1/2

1/2

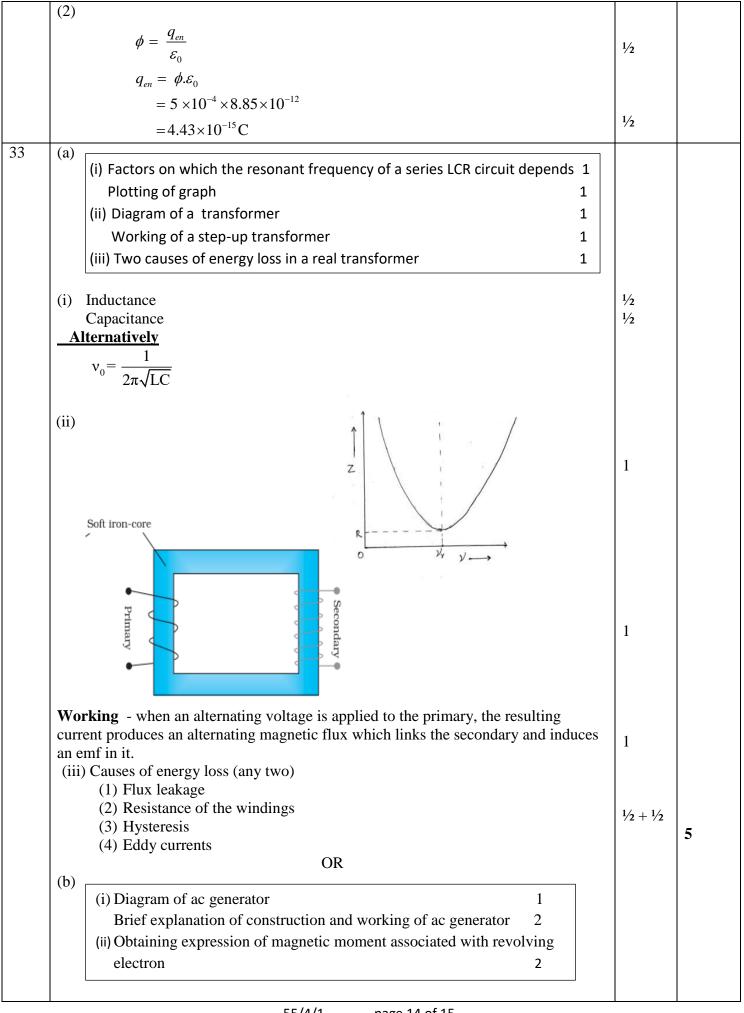
1/2

1/2

1/2

55/4/1

page 13 of 15



(i)

Coil
Axle

Slip
rings
Alternating emf

<u>Construction</u> – It consists of a coil placed in a magnetic field. The coil is mounted on a rotor shaft. The ends of the coil are connected to an external circuit by means of slip rings and brushes.

<u>Alternatively</u>

If a student draws only a labeled diagram of ac generator give 2 marks for construction and diagram.

<u>Working</u> – The coil is rotated in the uniform magnetic field by some external means. The rotation of the coil causes the magnetic flux through it to change, so an emf is induced in the coil.

<u>Alternatively</u>

If a student derives $e = e_0 \sin \omega t$ give one mark for working.

(ii) The equivalent current

$$I = \frac{q}{t} = \frac{e}{\frac{2\pi r}{v}} = \frac{ev}{2\pi r}$$

Mangetic moment of revolving electron

$$m = IA$$

$$= \frac{ev}{2\pi r} \times \pi r^{2}$$

$$= \frac{1}{2} evr$$



1

1

1/2

1/2

1/2

1/2

Marking Scheme Strictly Confidential (For Internal and Restricted use only) Senior School Certificate Examination, 2024

SUBJECT PHYSICS (CODE 55/4/2)

<u>Gen</u>	eral Instructions: -
1	You are aware that evaluation is the most important process in the actual and correct assessment of the candidates. A small mistake in evaluation may lead to serious problems which may affect the future of the candidates, education system and teaching profession. To avoid mistakes, it is requested that before starting evaluation, you must read and understand the spot evaluation guidelines carefully.
2	"Evaluation policy is a confidential policy as it is related to the confidentiality of the examinations conducted, Evaluation done and several other aspects. Its' leakage to public in any manner could lead to derailment of the examination system and affect the life and future of millions of candidates. Sharing this policy/document to anyone, publishing in any magazine and printing in News Paper/Website etc may invite action under various rules of the Board and IPC."
3	Evaluation is to be done as per instructions provided in the Marking Scheme. It should not be done according to one's own interpretation or any other consideration. Marking Scheme should be strictly adhered to and religiously followed. However, while evaluating, answers which are based on latest information or knowledge and/or are innovative, they may be assessed for their correctness otherwise and due marks be awarded to them. In class-X, while evaluating two competency-based questions, please try to understand given answer and even if reply is not from marking scheme but correct competency is enumerated by the candidate, due marks should be awarded.
4	The Marking scheme carries only suggested value points for the answers These are in the nature of Guidelines only and do not constitute the complete answer. The students can have their own expression and if the expression is correct, the due marks should be awarded accordingly.
5	The Head-Examiner must go through the first five answer books evaluated by each evaluator on the first day, to ensure that evaluation has been carried out as per the instructions given in the Marking Scheme. If there is any variation, the same should be zero after delibration and discussion. The remaining answer books meant for evaluation shall be given only after ensuring that there is no significant variation in the marking of individual evaluators.
6	Evaluators will mark($\sqrt{\ }$) wherever answer is correct. For wrong answer CROSS 'X" be marked. Evaluators will not put right ($\sqrt{\ }$) while evaluating which gives an impression that answer is correct and no marks are awarded. This is most common mistake which evaluators are committing.
7	If a question has parts, please award marks on the right-hand side for each part. Marks awarded for different parts of the question should then be totaled up and written in the left-hand margin and encircled. This may be followed strictly.
8	If a question does not have any parts, marks must be awarded in the left-hand margin and

55/4/2

Page 1 of 16



	encircled. This may also be followed strictly.
9	If a student has attempted an extra question, answer of the question deserving more marks should be retained and the other answer scored out with a note "Extra Question".
10	No marks to be deducted for the cumulative effect of an error. It should be penalized only once.
11	A full scale of marks 0 to 70 (example 0 to 80/70/60/50/40/30 marks as given in Question Paper) has to be used. Please do not hesitate to award full marks if the answer deserves it.
12	Every examiner has to necessarily do evaluation work for full working hours i.e., 8 hours every day and evaluate 20 answer books per day in main subjects and 25 answer books per day in other subjects (Details are given in Spot Guidelines). This is in view of the reduced syllabus and number of questions in question paper.
13	 Ensure that you do not make the following common types of errors committed by the Examiner in the past:- Leaving answer or part thereof unassessed in an answer book. Giving more marks for an answer than assigned to it. Wrong totaling of marks awarded on an answer. Wrong transfer of marks from the inside pages of the answer book to the title page. Wrong question wise totaling on the title page. Wrong totaling of marks of the two columns on the title page. Wrong grand total. Marks in words and figures not tallying/not same. Wrong transfer of marks from the answer book to online award list. Answers marked as correct, but marks not awarded. (Ensure that the right tick mark is correctly and clearly indicated. It should merely be a line. Same is with the X for incorrect answer.) Half or a part of answer marked correct and the rest as wrong, but no marks awarded.
14	While evaluating the answer books if the answer is found to be totally incorrect, it should be marked as cross (X) and awarded zero (0)Marks.
15	Any unassessed portion, non-carrying over of marks to the title page, or totaling error detected by the candidate shall damage the prestige of all the personnel engaged in the evaluation work as also of the Board. Hence, in order to uphold the prestige of all concerned, it is again reiterated that the instructions be followed meticulously and judiciously.
16	The Examiners should acquaint themselves with the guidelines given in the "Guidelines for Spot Evaluation" before starting the actual evaluation.
17	Every Examiner shall also ensure that all the answers are evaluated, marks carried over to the title page, correctly totaled and written in figures and words.
18	The candidates are entitled to obtain photocopy of the Answer Book on request on payment of the prescribed processing fee. All Examiners/Additional Head Examiners/Head Examiners are once again reminded that they must ensure that evaluation is carried out strictly as per value points for each answer as given in the Marking Scheme.

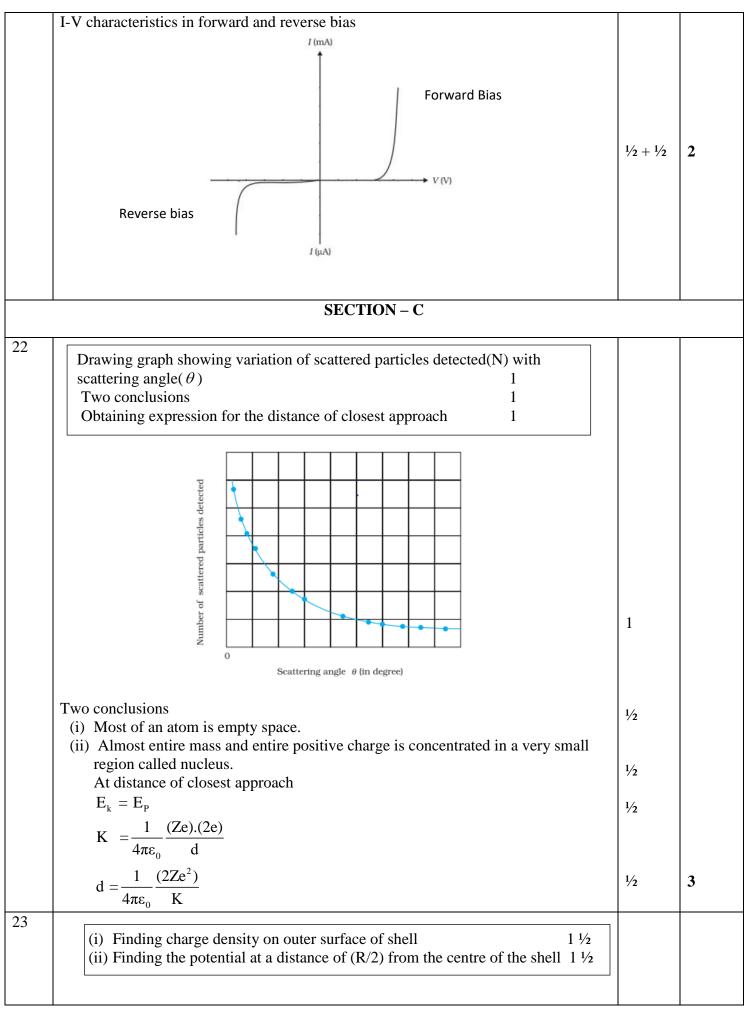
	MARKING SCHEME : PHYSICS (042) CODE : 55/4/2		
Q.NO	VALUE POINTS/EXPECTED ANSWERS	MARKS	TOTAL MARKS
1	SECTION - A	1	1
1	$(A) \frac{11}{48} \frac{q}{\pi \varepsilon_0 L}$	1	1
2	(D) $q_3 > q_1 > q_2$	1	1
3	(A) Small and negative.	1	1
4	(A) R	1	1
5	(C) Helical path.	1	1
6	(A) There is a minimum frequency of incident radiation below which no electrons are emitted.	1	1
7	(A)Zero	1	1
8	$(C) r_n \alpha n^2$	1	1
9	(B) 20 mA	1	1
10	(B) 1 mA	1	1
11	(D) Close together and weaker in intensity.	1	1
12	No option is correct, award 1 mark.	1	1
13	(C) Assertion (A) is true and Reason (R) is false.	1	1
14	(A) Both assertion (A) and Reason (R) are true and Reason (R) is the correct explanation of Assertion(A).	1	1
15	(D) Both Assertion (A) and Reason (R) are false.	1	1
16	(B) Both assertion (A) and Reason (R) are true and Reason (R) is not the correct explanation of Assertion(A).	1	1
	SECTION – B		
17	(a) Finding nature and position of image 2		
	Using refraction formula at spherical surface from denser to rarer medium $n_1 = \text{refractive index of denser medium}$ $n_1 = \text{refractive index of denser medium}$		
	n_2 = refractive index of denser medium $\frac{n_1}{v} - \frac{n_2}{u} = \frac{n_1 - n_2}{R}$	1/2	
	$u = -20 \text{ cm}$, $R = -40 \text{ cm}$, $n_1 = 1$, $n_2 = 1.5$ $\frac{1}{v} - \frac{1.5}{(-20)} = \frac{1-1.5}{(-40)}$	1/2	
	$\frac{-\sqrt{-20}}{\sqrt{-40}} = \frac{-\sqrt{-40}}{\sqrt{-40}}$	1/2	
	v = -16 cm	1/2	2
	Nature of image is virtual. OR	/ 2	2
	(b) Finding the focal lengths of the objective and eyepiece 2		
	Distance between objective and eyepiece $fo + fe = 1.00 \text{ m} = 100 \text{ cm}$	1/2	
	Magnifying power		
	$ m = \frac{\text{fo}}{\text{fe}} = 19$	1/2	
	On solving		
	fo = 95 cm = 0.95 m	1/2	
	fe = 5 cm = 0.05 m	1/2	

Page 3 of 16

Defining matter waves 1		
Arranging de Broglie wavelength in increasing order 1		
The waves associated with every moving particle are called matter waves.	1	
$\lambda = \frac{h}{\sqrt{2mK}}$		
For same kinetic energy, $\lambda \alpha \frac{1}{\sqrt{m}}$	1/2	
$\begin{array}{c c} m_{\alpha} > m_{p} > m_{e} \\ \therefore \lambda_{\alpha} < \lambda_{p} < \lambda_{e} \end{array}$	1/2	2
Finding refractive index of the medium 2		
60	1/2	
60,18		
From snell's law, μ .sin i = μ_m .sin r	1/2	
$\mu.\sin 60^0 = \mu_m.\sin 90^0$	1/2	
$\mu_{\rm m} = \mu \cdot \frac{\sqrt{3}}{2}$		
	1/2	2
$\frac{\textbf{Alternatively}}{\mu} = \frac{1}{\sin G}$	1	
Sin C		
$\frac{\mu}{\mu_m} = \frac{1}{\sin 60^0}$ $\mu_m = \frac{\sqrt{3}}{2} \mu$	1/2	
$\sqrt{3}$	1/	
	1/2	
(i) Finding resistance $\left(\frac{R_A}{R_B}\right)$		
(ii) Finding resistivity $\left(\frac{\sigma_A}{\sigma_B}\right)$		
(i) Slope of I - V graph = $\left(\frac{\Delta I}{\Delta V}\right) = \frac{I}{R}$	1/2	
55/4/2 Page 4 of 16		

Page 4 of 16

(ii)	$\frac{R_{A}}{R_{B}} = \frac{\text{Slope of B}}{\text{Slope of A}}$ $= \frac{\tan 45^{0}}{\tan 30^{0}}$ $\frac{R_{A}}{R_{B}} = \sqrt{3}$ $\frac{\sigma_{A}}{\sigma_{B}} = \frac{R_{A} \frac{A_{A}}{l_{A}}}{R_{B} \frac{A_{B}}{l_{B}}}$ $= \frac{R_{A}}{R_{B}} \cdot \frac{A_{A}}{A_{B}} \cdot \frac{l_{B}}{l_{A}}$ $= \sqrt{3} \times \frac{4}{1} \times \frac{2}{1}$ $= 8\sqrt{3}$	1/2	2
21 (i)	Drawing of circuit diagram of p-n junction diode (i) Forward bias (ii) Reverse bias 1/2 I-V charcteristics in forward and reverse bias Voltmeter(V) Woltmeter(V) Woltmeter(V) Woltmeter(V) Switch Microammeter (µA) Switch	1/2	



1	i) When a point charge Q is placed at the centre of the shell, a charge (-Q) is	1	
	induced at its inner surface, consequently a net charge on outer surface of the	1	
	shell = $q + Q$		
	Charge density on outer surface of the shell		
		1/2	
	$\sigma = \frac{ch \arg e}{Area}$		
	$=\frac{q+Q}{4\pi R^2}$		
(ii) Potential due to shell at a distance of (R/2) from the centre of the shell		
		1/	
	$V_1 = \frac{1}{4\pi\varepsilon_0} \frac{q}{R}$	1/2	
	o de la companya de		
	Potential due to charge Q at a distance of $(R/2)$ from the centre of the shell		
	$V_2 = \frac{1}{4\pi\varepsilon_0} \cdot \frac{Q}{R_2}$	1/2	
	$4\pi\varepsilon_0$ κ_2		
	Net potential at a distance of $(R/2)$ from the centre of the shell		
	$V = V_2 + V_2$		
		1/	
	$V = \frac{1}{4\pi\varepsilon_0 R}(q + 2Q)$	1/2	3
24	$+nc_0 \Lambda$		
24	(a) Difference between nuclear fission and fusion (1)		
	(b) Calculating energy released in fission (2)		
	(b) Calculating energy released in fission (2)		
(8	a) In nuclear fission, a heavy nucleus splits into two or more lighter nuclei and		
	energy is released.	1/2	
	In nuclear fusion, lighter nuclei combine together a form a heavy nucleus and		
	larger amount of energy is released.	1/2	
	220		
	(b) Number of atoms in 1 g of ₉₄ Pu ²³⁹		
	6.023×10^{23}		
	=		
	$= 2.5 \times 10^{21}$	1	
		1	
	Energy released in fission of 1 g of $_{94}Pu^{239}$,		
	$E = 180 MeV \times 2.5 \times 10^{21}$		
	$E = 4.5 \times 10^{23} \text{ MeV}$	1	3
25			
	Finding magnitude and direction of the net magnetic field at point P_1 1 $\frac{1}{2}$		
	Finding magnitude and direction of the net magnetic field at point P_2 1 $\frac{1}{2}$		
	Net magnetic field at point P ₁		
		1/	
	$B = B_{y(wire)} - B_{x(wire)}$	1/2	
	$\mu_0 I_1 \qquad \mu_0 I_2$		
	$=rac{\mu_{0}I_{1}}{2\pi r}-rac{\mu_{0}I_{2}}{2\pi r}$		
	$=\frac{\mu_0}{2\pi\times2}(5-3)$		
		1/2	
	$B = 2 \times 10^{-7} T$	/ 2	
<u> </u>		I .	<u> </u>

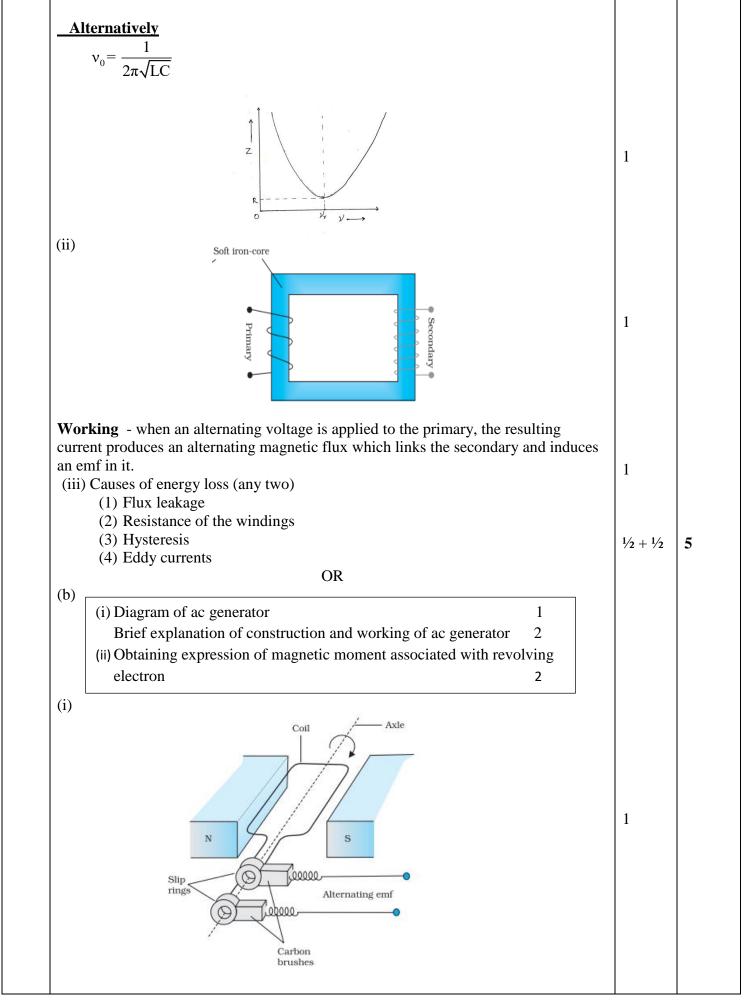
Page 7 of 16

	The direction of net magnetic field is along –ve z-axis.	1/2	
	Net magnetic field at point P ₂		
	$B = B_{y(wire)} + B_{x(wire)}$	1/2	
	$=rac{\mu_{0}I_{1}}{2\pi r}+rac{\mu_{0}I_{2}}{2\pi r}$		
	$=\frac{4\mu_0}{2\pi\times 1}(5+3)$		
	$=rac{4\mu_0}{\pi}$		
	π = 16×10^{-7} T	1/2	
	The direction of net magnetic field is along +ve z-axis.	1/2	3
26	Defining displacement current 1		
	Difference between Displacement current and conduction current Justification of the continuity of current in the circuit 1		
	Displacemnt current is the current which arises due to rate of change of electric field.	1	
	Displacement current is due to varying electric field.	1/2	
	Conduction current is due to motion of electrons in the presence of electric field.	1/2	
	When the capacitor is being charged by a source of emf, the electric field between the plates of capacitor changes with time. It produces a displacement current i_d	1	
	whose magnitude is equal to conduction current i _c . Therefore the current is continious	1	3
	in the circuit.		
27	Finding current in the arm AB 1½		
27	Finding current in the arm BC 1 ½		
	Circuit diagram with distribution of current		
	A -> MMW-rC		
	$\begin{array}{c c} A & \longrightarrow & & & & & & & & & & \\ \hline & 5\Omega & & & & & & & & \\ \hline & 5\Omega & & & & & & & & \\ \hline \end{array}$		
	N 10 C	1	
	11 10Ω 10Ω 10Ω		
	I-I,		
	N I MI I D 5V LOV		
	Using Kirchhoff's voltage rule		
	In closed loop ABMNA,		
	$-5I_1 + 10(I - I_1) - 5 = 0 (1)$	1/2	
	In closed loop ACDNA		
	$-5I - 20I + 10 - 5 - 5I_1 = 0 (2)$	1/2	
	55/4/2 Page 8 of 16	•	

Page 8 of 16

	Solving eq (1) and (2)		
	$I_1 = -\frac{3}{17} \text{ A and } I = \frac{4}{17}$		
	Magnitude of current in arm AB = $\frac{3}{17}$ A	1/2	
	Magnitude of current in arm $BC = \frac{4}{17} A$	1/2	3
28	(a) (i) Defining mutual inductance SI unit of mutual inductance (ii) Deriving expression for mutual inductance 2		
	 (i) Mutual inductance between two coils is defined as the magnetic flux associated with a coil when unit current flows through neighbouring coil. Alternatively Mutual inductance between two coils is defined as the magnitude of induced emf in a coil when the rate of change of current in neighbouring coil is unity. 	1/2	
	SI unit of mutual inductance is henry(H). (ii)	1/2	
	N_1 turns N_2 turns		
	When current I_2 flows in outer solenoid, the resulting flux linkage with inner solenoid. $N_1 \phi_1 = N_1 B_2 A_1$ $N_1 \phi_1 = N_1 \left(\frac{\mu_0 N_2 I_2}{l} \right) \pi r_1^2$	1/2	
	$N_{1}\phi_{1} = \frac{\mu_{0}N_{1}N_{2}\pi r_{1}^{2}I_{2}}{l} \qquad$	1/2	
	From equations (1) and (2)	1/2	3
	$M_{12} = \frac{\mu_0 N_1 N_2 \pi r_1^2}{l}$ OR		
	(b) Defining ferromagnetic materials 1 Explanation of ferromagnetism with diagram 2		

	Ferromagnetic substances are those which get strongly magnetised when placed in an external magnetic field.	1	
	$\begin{array}{c} \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\$	1/2 + 1/2	
	In absence of external magnetic field, domains are randomly oriented and it exhibits weak magnetisation. In the presence of external magnetic field domains orient themselves in the direction of magnetic field and it exhibits strong magnetisation.	1/2	
	SECTION - D		
29	(i) (B) $\frac{-5}{3}D$ (ii) (C) $\frac{3}{2}$	1	
	(iii) (C) $\frac{1}{2}$ (iii) (A) increases when a lens is dipped in water. (iv) (a) (B) 10 cm, right from lens. OR (b) (A) real, 24 cm	1 1 1	4
30	(i) (B) 0.01 eV (ii) (D) 5×10 ²² m ⁻³ (iii) (a) (C) Electrons diffuse from n-region into p-region and holes diffuse from p-region to n-region. OR	1 1 1	
	(b) (A) Diffusion current is large and drift current is small. (iv) (D) 50 Hz, 100 Hz.	1	4
31	SECTION - E		
31	(i) Factors on which the resonant frequency of a series LCR circuit depends 1 Plotting of graph (ii) Diagram of a transformer Working of a step-up transformer 1 (iii) Two causes of energy loss in a real transformer		
	(i) Inductance Capacitance	1/2 1/2	



	<u>Construction</u> – It consists of a coil placed in a magnetic field. The coil is mounted on a rotor shaft. The ends of the coil are connected to an external circuit by means of slip rings and brushes. <u>Alternatively</u>	1	
	If a student draws only a labeled diagram of ac generator give 2 marks for construction and diagram. Working – The coil is rotated in the uniform magnetic field by some external means.		
	The rotation of the coil causes the magnetic flux through it to change, so an emf is induced in the coil. Alternatively	1	
	If a student derives $e = e_0 \sin \omega t$ give one mark for working.		
	(ii) The equivalent current		
	$I = \frac{q}{t} = \frac{e}{2\pi r} = \frac{ev}{2\pi r}$	1/2	
	Mangetic moment of revolving electron $m = IA$	1/2	
	$=\frac{\mathrm{ev}}{2\pi\mathrm{r}} imes\pi\mathrm{r}^2$	1/2	
	$=\frac{1}{2}$ evr	1/2	
32	(i) Obtaining expression for capacitance 3 (ii) Finding capacitance of capacitors 2		
	a) (i) Electric field in air between plates $E_0 = \frac{\sigma}{\varepsilon_0}$ Electric field inside the dielectric	1/2	
	$E = \frac{\sigma}{\varepsilon_0 K} \qquad \qquad \underbrace{\leftarrow t \rightarrow}_{\leftarrow t \rightarrow}$	1/2	
	Potential difference between the plates $V=E_0(d-t)+Et$	1/2	
	$V = \frac{\sigma}{\varepsilon_0} \left[d - t + \frac{t}{K} \right]$ $V = \frac{q}{A\varepsilon_0} \left[d - t + \frac{t}{K} \right]$	1/2	
	Capacitance $C = \frac{q}{r}$	1/2	
	$C = \frac{q}{V}$ $C = \frac{A\epsilon_0}{d-t + \frac{t}{K}}$		
	$C = \frac{A\varepsilon_0}{d - t \left(1 - \frac{1}{K}\right)}$	1/2	

$$\frac{1}{2} \left(\frac{C_1 C_2}{C_1 + C_2} \right) V^2 = 40 \times 10^{-3} \text{ J}....(1)$$

1/2

Energy stored in parallel combination

$$\frac{1}{2} (C_1 + C_2) V^2 = 250 \times 10^{-3} J....(2)$$

1/2

Substituting value of V=100 V in eq (1) and (2), on solving

$$C_1 = 4 \times 10^{-5} \, \text{F or } 40 \, \mu\text{F}$$

$$C_2 = 1 \times 10^{-5} \, \text{F or } 10 \, \mu\text{F}$$

1/2

1/2

5

b)

- i) Showing electric field at a point due to a uniformly charged infinite plane sheet
- 3

- ii) Calculating
- (1) electric flux through the cube

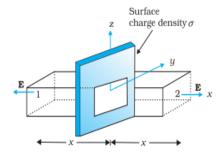
OR

(2) charge enclosed by cube

1

1

(i)



$$\oint \vec{E}.d\vec{s} = \int_{1} \vec{E}.d\vec{s} + \int_{2} \vec{E}.d\vec{s}$$

$$= 2EA$$

1/2

From Gauss's law

$$\oint \vec{E}.d\vec{s}\,=\frac{q}{\epsilon_0}$$

1/2

$$2EA = \frac{\sigma A}{\epsilon_0}$$

1/2

$$E = \frac{\sigma}{2\epsilon_0}$$

Vectorially
$$\vec{E} = \frac{\sigma}{2\epsilon_0} \hat{n}$$

1/2

Electric field is normally outward of the sheet.

	(ii)		
	(1) Electric flux through the cube		
	$\phi = \phi_L + \phi_R$	1/2	
	$\phi = \int \vec{E}_L . d\vec{s} + \int \vec{E}_R . d\vec{s}$		
	$= -2 \times 100 \times 10^{-4} + [5 \times (10 \times 10^{-2})^{2} + 2] \times 100 \times 10^{-4}$		
	$\phi = 5 \times 10^{-4} \text{ Nm}^2 \text{C}^{-1}$	1/2	
	(2)		
	$\phi=rac{q_{en}}{arepsilon_0}$	1/2	
	$q_{en} = \phi.\varepsilon_0$		
	$= 5 \times 10^{-4} \times 8.85 \times 10^{-12}$	1/2	
	$=4.43\times10^{-15}$ C	72	
33	a) i) Drawing of ray diagram Obtaining mirror equation ii) Reason for using multi-component lenses iii) Finding magnification produced by the objective 1		
	i) A B P B' F C	1	
	For paraxial rays MP can be considered to be a straight line perpendicular to CP, Therefore right angled triangles ABF and MPF are similar $\frac{BA}{PM} = \frac{BF}{FP}$		
	Or $\frac{BA}{BA} = \frac{BF}{FP}$ (:: PM = AB)(1)	1/2	
	BA FP Since \angle APB = \angle A'PB , the right angled triangles A'PB and ABP are also		
	similar		
	Therefore, $\frac{B'A'}{BA} = \frac{B'P}{BP}$ (2)	1/2	
	Comparing eq (1) and (2), we get		
	$\frac{B'F}{FP} = \frac{B'P}{BP}$		
	PF-PB' B'P		
	${\text{FP}} = {\text{BP}}$		
	Using sign convention $PF = f$, $PB' = +v$, $PB = -u$	1/2	
	FF/4/2 Page 14 of 10		

on solving	1	1=	= 1
6	V	u	f

- ii) To improve image quality by minimizing various optical aberrations in lenses.
- Magnification produced by compound microscope

$m=m_o \times$	m _e
----------------	----------------

$$m_{o} = \frac{m}{m_{e}} = \frac{m}{\left|\frac{D}{fe}\right|}$$

$$m_o = \frac{200}{\frac{25}{2}} = 16$$

1/2

1

 $\frac{1}{2}$

1/2

5

OR

- (b)
- i) Difference between a wavefront and a ray 1
- ii) Statement of Huygens' principle 1 Verification of the law of reflection $1\frac{1}{2}$ iii) Finding wavelength of light 1 1/2
- i) Wavefront is a surface of constant phase.

1/2

Alternatively Locus of points, which oscillate in phase

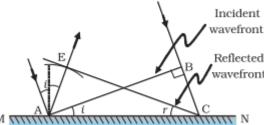
Ray - The straight line path along which light travels (or energy propagates). **Alternatively** – Ray is normal to wave front.

1/2

ii) **Huygens' Principle** Each point of the wave front is the source of secondary disturbance and the wavelets emanating from the points spread out in all directions with speed of wave. The wavelets emanating from wave front are usually referred to as secondary wavelets. A common tangent to all these spheres

1

gives the new position of the wave front at a later time.



1

Triangles EAC and BAC are congruent therefore $\angle i = \angle r$

1/2

Position of 4th bright fringe iii)

$$x_{_{4(bright)}}\!=\!4\frac{D\lambda}{d}$$

1/2

Position of 2nd dark fringe

$$x_{2(dark)} = \frac{3}{2} \; \frac{D\lambda}{d}$$

1/2

$$x_{4(bright)} - x_{2(dark)} = 5mm$$

$$4\frac{D\lambda}{d} - \frac{3}{2}\frac{D\lambda}{d} = 5 \times 10^{-3}$$

1/2

 $\lambda = 6 \times 10^{-6}$ m

Marking Scheme Strictly Confidential (For Internal and Restricted use only) Senior School Certificate Examination, 2024

SUBJECT PHYSICS (CODE 55/4/3)

Gene	eral Instructions: -
1	You are aware that evaluation is the most important process in the actual and correct assessment of the candidates. A small mistake in evaluation may lead to serious problems which may affect the future of the candidates, education system and teaching profession. To avoid mistakes, it is requested that before starting evaluation, you must read and understand the spot evaluation guidelines carefully.
2	"Evaluation policy is a confidential policy as it is related to the confidentiality of the examinations conducted, Evaluation done and several other aspects. Its' leakage to public in any manner could lead to derailment of the examination system and affect the life and future of millions of candidates. Sharing this policy/document to anyone, publishing in any magazine and printing in News Paper/Website etc may invite action under various rules of the Board and IPC."
3	Evaluation is to be done as per instructions provided in the Marking Scheme. It should not be done according to one's own interpretation or any other consideration. Marking Scheme should be strictly adhered to and religiously followed. However, while evaluating, answers which are based on latest information or knowledge and/or are innovative, they may be assessed for their correctness otherwise and due marks be awarded to them. In class-X, while evaluating two competency-based questions, please try to understand given answer and even if reply is not from marking scheme but correct competency is enumerated by the candidate, due marks should be awarded.
4	The Marking scheme carries only suggested value points for the answers These are in the nature of Guidelines only and do not constitute the complete answer. The students can have their own expression and if the expression is correct, the due marks should be awarded accordingly.
5	The Head-Examiner must go through the first five answer books evaluated by each evaluator on the first day, to ensure that evaluation has been carried out as per the instructions given in the Marking Scheme. If there is any variation, the same should be zero after delibration and discussion. The remaining answer books meant for evaluation shall be given only after ensuring that there is no significant variation in the marking of individual evaluators.
6	Evaluators will mark($\sqrt{\ }$) wherever answer is correct. For wrong answer CROSS 'X" be marked. Evaluators will not put right ($\sqrt{\ }$) while evaluating which gives an impression that answer is correct and no marks are awarded. This is most common mistake which evaluators are committing.
7	If a question has parts, please award marks on the right-hand side for each part. Marks awarded for different parts of the question should then be totaled up and written in the left-hand margin and encircled. This may be followed strictly.
8	If a question does not have any parts, marks must be awarded in the left-hand margin and

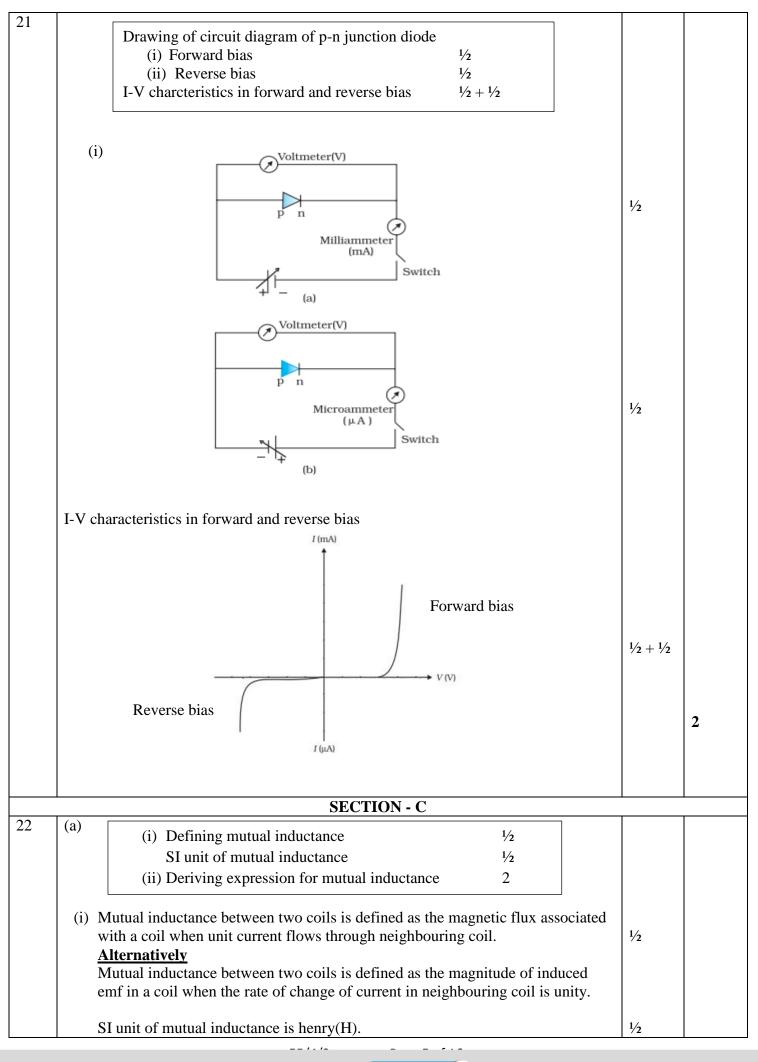


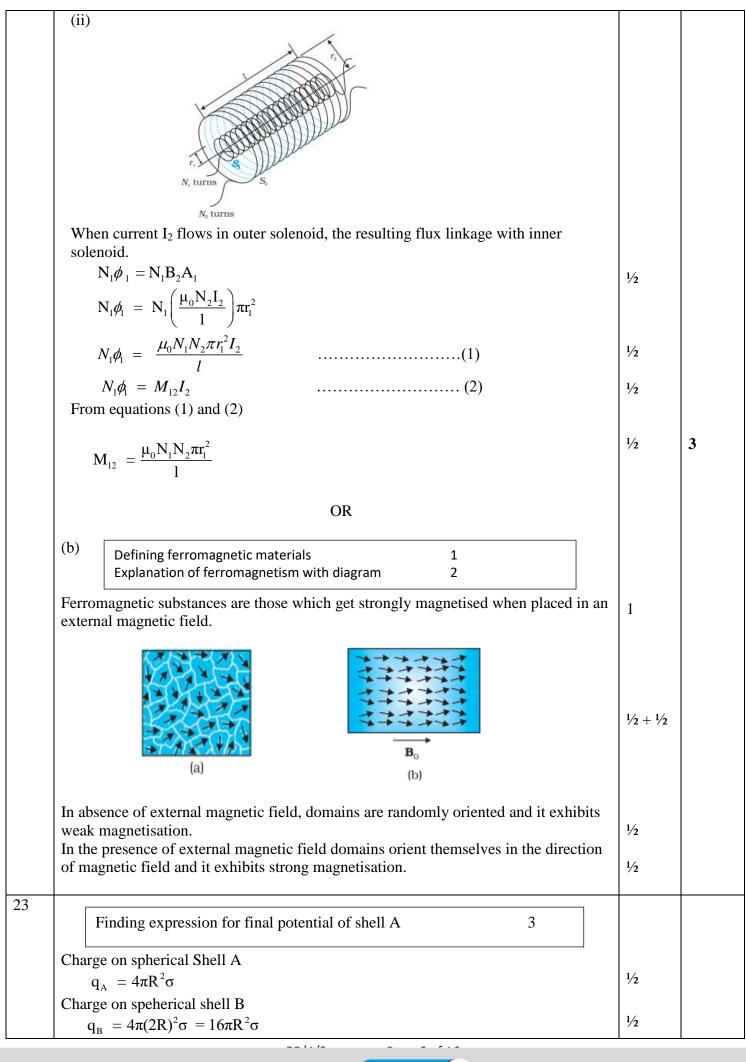
	encircled. This may also be followed strictly.
9	If a student has attempted an extra question, answer of the question deserving more marks should be retained and the other answer scored out with a note "Extra Question".
10	No marks to be deducted for the cumulative effect of an error. It should be penalized only once.
11	A full scale of marks 0 to 70_(example 0 to 80/70/60/50/40/30 marks as given in Question Paper) has to be used. Please do not hesitate to award full marks if the answer deserves it.
12	Every examiner has to necessarily do evaluation work for full working hours i.e., 8 hours every day and evaluate 20 answer books per day in main subjects and 25 answer books per day in other subjects (Details are given in Spot Guidelines). This is in view of the reduced syllabus and number of questions in question paper.
13	 Ensure that you do not make the following common types of errors committed by the Examiner in the past:- Leaving answer or part thereof unassessed in an answer book. Giving more marks for an answer than assigned to it. Wrong totaling of marks awarded on an answer. Wrong transfer of marks from the inside pages of the answer book to the title page. Wrong question wise totaling on the title page. Wrong totaling of marks of the two columns on the title page. Wrong grand total. Marks in words and figures not tallying/not same. Wrong transfer of marks from the answer book to online award list. Answers marked as correct, but marks not awarded. (Ensure that the right tick mark is correctly and clearly indicated. It should merely be a line. Same is with the X for incorrect answer.) Half or a part of answer marked correct and the rest as wrong, but no marks awarded.
14	While evaluating the answer books if the answer is found to be totally incorrect, it should be marked as cross (X) and awarded zero (0)Marks.
15	Any unassessed portion, non-carrying over of marks to the title page, or totaling error detected by the candidate shall damage the prestige of all the personnel engaged in the evaluation work as also of the Board. Hence, in order to uphold the prestige of all concerned, it is again reiterated that the instructions be followed meticulously and judiciously.
16	The Examiners should acquaint themselves with the guidelines given in the "Guidelines for Spot Evaluation" before starting the actual evaluation.
17	Every Examiner shall also ensure that all the answers are evaluated, marks carried over to the title page, correctly totaled and written in figures and words.
18	The candidates are entitled to obtain photocopy of the Answer Book on request on payment of the prescribed processing fee. All Examiners/Additional Head Examiners/Head Examiners are once again reminded that they must ensure that evaluation is carried out strictly as per value points for each answer as given in the Marking Scheme.



	MARKING SCHEME : PHYSICS (042)		
Q.NO	CODE : 55/4/3 VALUE POINTS/EXPECTED ANSWERS	MARKS	TOTAL
Q.110		WIAKKS	MARKS
1	SECTION - A	1	1
2	(A) 2 pE	1	1
2	(B) Repulsive and $\frac{q\lambda}{2\pi\epsilon_0 x}$	1	1
2	· · · · · · · · · · · · · · · · · · ·		4
3	(A) Zero.	1	1
5	(D) Closer together and weaker in intensity. No option is correct, award 1 mark.	1	1
6	No option is correct, award 1 mark.	1	1
7	(A) R	1	1
8	(B) 1mA	1	1
9	$(C) \frac{1}{\sqrt{2}} \sqrt{(i_1^2 + i_2^2)}$	1	1
10	(A) There is a minimum frequency of incident radiation below which no electrons are emitted.	1	1
11	(A) Small and negative.	1	1
12	$(C) r_n \alpha n^2$	1	1
13	(A) Both assertion (A) and Reason (R) are true and Reason (R) is the correct explanation of Assertion(A).	1	1
14	(C) Assertion (A) is true and Reason (R) is false.	1	1
15	(B) Both assertion (A) and Reason (R) are true and Reason (R) is not the correct explanation of Assertion(A).	1	1
16	(D) Both Assertion (A) and Reason (R) are false.	1	1
	SECTION – B	1	T
17	(a) Finding nature and position of image 2		
	Using refraction formula at spherical surface from denser to rarer medium n_1 = refractive index of rarer medium		
	n_2 = refractive index of denser medium		
		1/2	
	$\frac{n_1}{v} - \frac{n_2}{u} = \frac{n_1 - n_2}{R}$		
	$u = -20 \text{ cm}$, R= -40 cm, $n_1 = 1$, $n_2 = 1.5$	1/2	
	$\frac{1}{v} - \frac{1.5}{(-20)} = \frac{1-1.5}{(-40)}$		
	v = -16 cm	1/2	
	Nature of image is virtual.	1/2	2
	OR		2
	(b) Finding the focal lengths of the objective and eyepiece 2		
	Distance between objective and eyepiece $fo + fe = 1.00 \text{ m} = 100 \text{ cm}$	1/2	
	Magnifying power		
	$ m = \frac{\text{fo}}{\text{fe}} = 19$	1/2	
	On solving		
	fo = 95 cm = 0.95 m	1/2	
	fe = 5 cm = 0.05 m	1/2	

18			
10	Finding $\frac{V_p}{}$ 2		
	Finding $\frac{V_p}{V_d}$ 2		
	Do Broglio wayalangth of proton		
	De Broglie wavelength of proton	1/2	
	$\lambda_{\rm p} = \frac{h}{\sqrt{2 meV_{\rm p}}}$		
	De Broglie wavelength of deutron		
		1/2	
	$\lambda_{\rm d} = \frac{h}{\sqrt{2(2m)eV_{\rm d}}}$, 2	
		17	
	$\frac{\lambda_{p}}{\lambda_{d}} = \frac{1}{2} = \frac{\sqrt{2(2m)eV_{d}}}{\sqrt{2meV_{p}}}$	1/2	
	On solving		
	$\frac{V_p}{V_d} = 8$	1/2	2
19			
	Finding refractive index of the medium 2		
	600	1/2	
	60 3 12		
	From snell's law, μ .sin i = μ_m .sin r	1/2	
	$\mu.\sin 60^0 = \mu_m.\sin 90^0$	1/2	
	$\mu_{\rm m} = \mu \cdot \frac{\sqrt{3}}{2}$	1/	
	Alternatively	1/2	2
	1	1	
	$\mu_{\rm ga} = \frac{1}{\sin C}$		
	μ _ 1	1/2	
	$\frac{1}{\mu_m} - \frac{1}{\sin 60^\circ}$, 2	
	$\frac{\mu}{\mu_m} = \frac{1}{\sin 60^0}$ $\mu_m = \frac{\sqrt{3}}{2}\mu$.,	
	$\mu_m = \frac{1}{2}\mu$	1/2	
20	Finding temperature of conductor 2		
	Thang temperature of conductor		
	$R_2 = R_1 + 25\% \text{ of } R_1 = 1.25R_1$	1/2	
	Temperature coefficient of resistance		
	$\alpha = \frac{R_2 - R_1}{R_1 \cdot \Delta T}$	1/2	
		17	
	$T_2 - 27 = \frac{1.25R_1 - R_1}{R_1 \times 2 \times 10^{-4}}$	1/2	
		1/2	2
	$T_2 = 1277 {}^{0}C$		





	After connecting by a wire, their potentials will become equal after sharing of		
	charge.	1.	
	$\frac{1}{4\pi\varepsilon_0}\frac{\mathbf{q}_A}{\mathbf{R}} = \frac{1}{4\pi\varepsilon_0}\frac{\mathbf{q}_B}{2\mathbf{R}}$	1/2	
	$4\pi\epsilon_0 R 4\pi\epsilon_0 2R$		
	$q_B = 2q_A$		
	From conservation of charge		
	$\mathbf{q}_{\mathrm{A}} + \mathbf{q}_{\mathrm{B}} = \mathbf{q}_{\mathrm{A}} + \mathbf{q}_{\mathrm{B}}$	1/2	
	$4\pi R^2 \sigma + 16\pi R^2 \sigma = 3q_A$		
	$q_A = \frac{20\pi R^2 \sigma}{3}$	1/2	
	Final potential of Shell A		
	$V_{A} = \frac{1}{4\pi\epsilon_{0}} \frac{q_{A}}{R}$		
	$4\pi\epsilon_0$ R		
	$V = 1 20\pi R^2 \sigma$		
	$V_A = \frac{1}{4\pi\epsilon_0} \frac{20\pi R^2 \sigma}{3R}$		
		1/2	3
	$V_A = \frac{5\sigma R}{3\varepsilon_0}$		
	Alternatively		
	Charge on spherical shell A		
	$q_A = 4\pi R^2 \sigma$	1/2	
	Charge on spherical shell B		
	$q_{\rm B} = 4\pi (2R)^2 \sigma = 16\pi R^2 \sigma$	1/2	
	After connecting by a wire, their potential will become equal after sharing of	, 2	
	charges Therefore the potential of shell A	1/2	
	$V_A = V_{common} = \frac{q_A + q_B}{C_A + C_B}$	1/2	
	$-\frac{4\pi R^2 \sigma + 16\pi R^2 \sigma}{4\pi R^2 \sigma}$	/2	
	$= \frac{4\pi\epsilon_0 R + 4\pi\epsilon_0 (2R)}{4\pi\epsilon_0 R + 4\pi\epsilon_0 (2R)}$	1/2	
	$=\frac{5\sigma R}{3\varepsilon_0}$	1/2	
24	300	/2	
21	Drawing graph showing variation of scattered particles detected (N) with		
	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$		
	Obtaining expression for the distance of closest approach 1		
	Comming empression for the distance of closest approach		
	cted		
	ss defe		
	barricic barricic		
	Itered 1		
	of scal		
	Number of scattered particles detected	1	
	Scattering angle θ (in degree)		
•		•	•

	Two conclusions		
	(i) Most of an atom is empty space.	1/2	
	(ii) Almost entire mass and entire positive charge is concentrated in a very small	/2	
	region called nucleus.		
	At distance of closest approach	1/2	
	$E_k = E_P$		
		1/2	
	$K = \frac{1}{4\pi\epsilon_0} \frac{(Ze).(2e)}{d}$		
	$d = \frac{1}{(2Ze^2)}$	1/2	
	$d = \frac{1}{4\pi\epsilon_0} \frac{(2Ze^2)}{K}$	/2	3
25			3
23	(i) Calculating effective resistance 2		
	(ii) Calculating power supplied by battery 1		
	$i) P = 10 \cdot 10 = 200$	1/2	
	i) $R_{ABC} = 10+10=20\Omega$		
	Equivalent resistance across AC		
	20×20	1/2	
	$R_{AC} = \frac{20 \times 20}{20 + 20} = 10\Omega$	72	
	Equivalent resistance across AD		
	$R_{AD} = \frac{20 \times 20}{20 + 20} = 10 \ \Omega$	1/2	
	$R_{AD} = \frac{10.52}{20 + 20} = 10.52$		
	Equivalent resistance across AM		
	$R_{AM} = \frac{20 \times 30}{20 + 30} = 12\Omega$	1/2	
	ii) Net resistance of circuit		
	$R_{net} = 12 + 10 + 8 = 30 \Omega$	1/2	
	Power supplied		
	\mathbf{V}^2		
	$P = \frac{V^2}{R_{net}}$		
	$=\frac{\left(6\right)^{2}}{30}$		
	$-{30}$		
	= 1.2 W	1/2	3
	Alternatively		
	Net resistance of circuit		
		1/2	
	$R_{net} = 12+10+8 = 30 \Omega$		
	3 – 1		
	$I = \frac{\varepsilon}{R_{\text{net}}}$		
	$= \frac{6}{30}$		
	= 0.2 A		
	0.2.1.		
	1.10		

	Power supplied		
	P = VI		
	$= 6 \times 0.2$		
	$=1.2\mathrm{W}$	1/2	
26	F: 1: 1 66		
	Finding magnitude of force 2 ½ Finding direction of force ½		
	Magnetic field at P due to infinite straight conductor carrying current $\vec{B} = \frac{\mu_0 I}{2\pi r} \hat{k}$	1/2	
	Force on charge q in this magnetic field $\vec{F} = q(\vec{v} \times \vec{B})$	1/2	
	$\vec{\mathbf{F}} = \mathbf{q} \left[(\mathbf{v}_0 \hat{\mathbf{j}}) \times \left(\frac{\mu_0 \mathbf{I}}{2\pi \mathbf{r}} \right) \hat{k} \right]$	1/2	
	$ec{\mathbf{F}} = rac{\mu_0 \mathbf{q} \mathbf{v}_0 \mathbf{I}}{2\pi \mathbf{r}} \hat{\mathbf{i}}$	1/2	
	The magnitude of force $\ F = rac{\mu_0 q v_0 I}{2\pi r}$	1/2	
	The direction of force on charge is along +ve X-axis.	1/2	3
28	Reasons for i) Difference in mode of interaction of electromagnetic wave with matter 1 ii) Containing water in food items to be heated in microwave 1 iii) Wearing facemask with glasses by welders during welding 1 (i) Since they have different wavelenghts and frequencies, they differ considerably in their mode of interaction with matter. (ii) Frequency of microwave matches with the resonant frequency of water molecules so that energy from wave is transferred to water molecules. (iii) To protect their eyes from large amount of ultraviolet rays produced by welding arcs. (a) Difference between nuclear fission and fusion (1) (b) Calculating energy released in fission (2) (a) In nuclear fission, a heavy nucleus splits into two or more lighter nuclei and energy is released.	1 1 1 1 1/2	3
	In nuclear fusion, lighter nuclei combine together a form a heavy nucleus and larger amount of energy is released. (b) Number of atoms in 1 g of ₉₄ Pu ²³⁹	1/2	
	$= \frac{6.023 \times 10^{23}}{239}$ $= 2.5 \times 10^{21}$	1	
		L	

	Energy released in fission of 1 g of $_{94}Pu^{239}$,		
	$E = 180 \text{MeV} \times 2.5 \times 10^{21}$		
	$E = 4.5 \times 10^{23} \text{ MeV}$	1	3
29	SECTION - D		
	 (i) (B) 0.01 eV (ii) (D) 5×10²² m⁻³ (iii) (a) (C) Electrons diffuse from n-region into p-region and holes diffuse from p-region to n-region. OR 	1 1 1	
	(b) (A) Diffusion current is large and drift current is small.		
	(iv) (D) 50 Hz, 100 Hz.	1	4
30	5		
	(i) (B) $\frac{-5}{3}D$ (ii) (C) $\frac{3}{2}$	1	
	(ii) (C) $\frac{3}{2}$	1	
	(iii) (A) increases when a lens is dipped in water. (iv) (a) (B) 10 cm, right from lens.	1 1	
	OR (b) (A) real, 24 cm		4
21	SECTION - E	<u> </u>	
31	a) (i) Obtaining expression for capacitance 3 (ii) Finding capacitance of capacitors 2		
	a) (i) Electric field in air between plates $E_0 = \frac{\sigma}{\varepsilon_0}$ Electric field inside the dielectric	1/2	
	$E = \frac{\sigma}{\varepsilon_0 K}$ $E = \frac{\sigma}{\varepsilon_0 K}$	1/2	
	Potential difference between the plates $V=E_0(d-t)+Et$	1/2	
	$V = \frac{\sigma}{\varepsilon_0} \left[d - t + \frac{t}{K} \right]$		
	$V = \frac{q}{A\varepsilon_0} \left[d - t + \frac{t}{K} \right]$ Capacitance	1/2	
		1/2	
	$C = \frac{q}{V}$ $C = \frac{A\varepsilon_0}{d-t + \frac{t}{K}}$		

$$C = \frac{A\varepsilon_0}{d - t \left(1 - \frac{1}{K}\right)}$$

ii) Total energy stored in series combination

$$\frac{1}{2} \left(\frac{C_1 C_2}{C_1 + C_2} \right) V^2 = 40 \times 10^{-3} \text{ J}....(1)$$

Energy stored in parallel combination

$$\frac{1}{2} (C_1 + C_2) V^2 = 250 \times 10^{-3} J....(2)$$

Substituting value of V=100~V in eq (1) and (2) , on solving

$$C_1 = 4 \times 10^{-5} \text{ F or } 40 \,\mu\text{F}$$

$$C_2 = 1 \times 10^{-5} \,\mathrm{F} \,\mathrm{or} \, 10 \,\mu\mathrm{F}$$

OR

b)

- i) Showing electric field at a point due to a uniformly charged infinite plane sheet
- ii) Calculating
- (1) electric flux through the cube

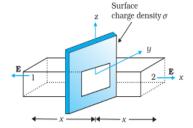
3

1

1

(2) charge enclosed by cube

(i)



$$\oint \vec{E}.d\vec{s} = \int_{1} \vec{E}.d\vec{s} + \int_{2} \vec{E}.d\vec{s}$$

$$=2EA$$

From Gauss's law

$$\oint \vec{E}.d\vec{s} = \frac{q}{\varepsilon_0}$$

$$2EA = \frac{\sigma A}{\varepsilon_0}$$

$$E = \frac{\sigma}{2\epsilon_0}$$

Vectorially $\vec{E} = \frac{\sigma}{2\epsilon_0} \hat{n}$

Electric field is normally outward of the sheet.

(ii) (1) Electric flux through the cube

$$\phi = \phi_L + \phi_R$$

$$\phi = \int \vec{E}_L \cdot d\vec{s} + \int \vec{E}_R \cdot d\vec{s}$$

$$\phi = \int E_L . d\vec{s} + \int E_R . d\vec{s}$$

$$= -2 \times 100 \times 10^{-4} + [5 \times (10 \times 10^{-2})^{2} + 2] \times 100 \times 10^{-4}$$

$$\phi = 5 \times 10^{-4} \text{ Nm}^2 \text{C}^{-1}$$

1/2

1/2

1/2

1/2

1/2

5

1

 $\frac{1}{2}$

1/2

1/2

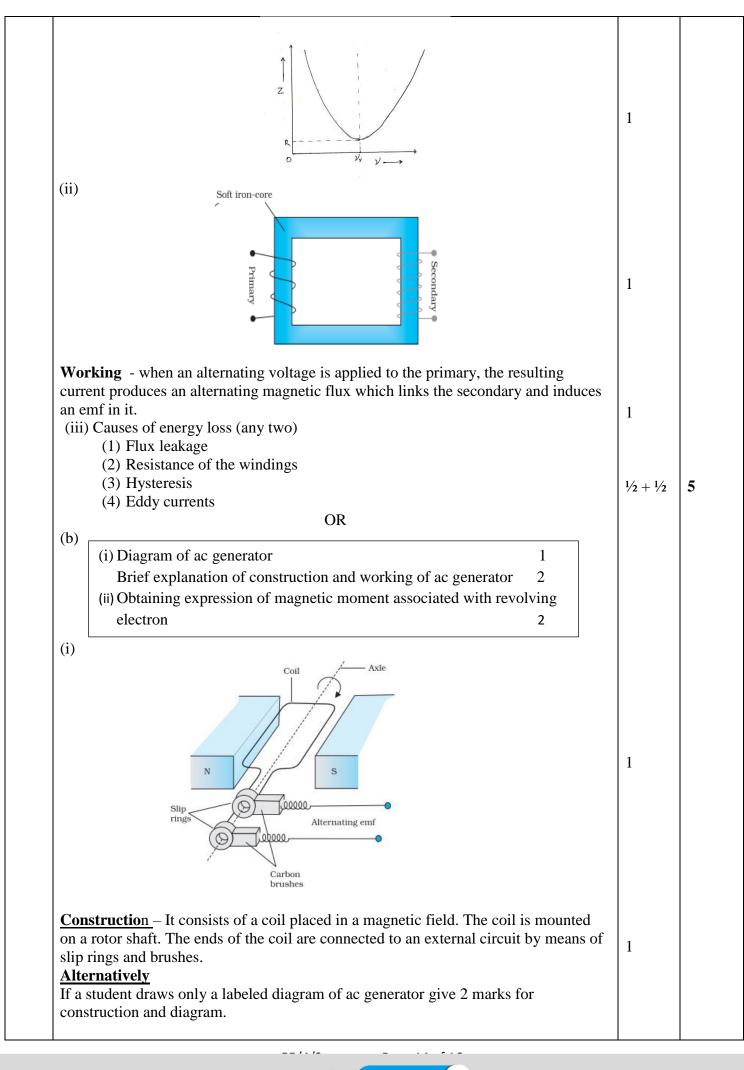
1/2

1/2

 $\frac{1}{2}$

	(2)		
	$\phi=rac{q_{en}}{arepsilon_0}$	1/2	
	\mathcal{E}_0		
	$q_{en} = \phi.\varepsilon_0$		
	$= 5 \times 10^{-4} \times 8.85 \times 10^{-12}$	1/	
	$=4.43\times10^{-15}$ C	1/2	
32	a) i) Drawing of ray diagram Obtaining mirror equation ii) Reason for using multi-component lenses iii) Finding magnification produced by the objective 1		
	i)		
	A B P B F C	1	
	For paraxial rays MP can be considered to be a straight line perpendicular to CP, Therefore right angled triangles \overrightarrow{ABF} and MPF are similar $\frac{\overrightarrow{BA}}{\overrightarrow{PM}} = \frac{\overrightarrow{BF}}{\overrightarrow{FP}}$		
	Or $\frac{B'A'}{BA} = \frac{B'F}{FP}$ (:: PM = AB)(1)	1/2	
	Since \angle APB = \angle A'PB', the right angled triangles A'PB' and ABP are also similar		
	Therefore, $\frac{B'A'}{BA} = \frac{B'P}{BP}$ Comparing eq (1) and (2), we get $\frac{B'F}{FP} = \frac{B'P}{BP}$ (2)	1/2	
	$\frac{PF - PB'}{FP} = \frac{B'P}{BP}$		
	Using sign convention $PF = f, PB' = +v , PB = -u$	1/2	
	on solving $\frac{1}{v} + \frac{1}{u} = \frac{1}{f}$	1/2	
	ii) To improve image quality by minimizing various optical aberrations in lenses.	1	
	iii) Magnification produced by compound microscope $m = m_o \times m_e$	1/2	
	$m_{o} = \frac{m}{m_{e}} = \frac{m}{\left \frac{D}{fe}\right }$		

	$m_o = \frac{200}{25} = 16$	1/2	5
	$\frac{23}{2}$		
	OR		
	(b) i) Difference between a wavefront and a ray 1		
	ii) Statement of Huygens' principle 1		
	Verification of the law of reflection 1 ½		
	iii) Finding wavelength of light 1 ½		
	i) Wavefront is a surface of constant phase.	1/2	
	<u>Alternatively</u> Locus of points, which oscillate in phase <u>Ray -</u> The straight line path along which light travels (or energy propagates).	1/2	
	<u>Alternatively –</u> Ray is normal to wave front. ii) <u>Huygens' Principle</u> Each point of the wave front is the source of secondary	/2	
	disturbance and the wavelets emanating from the points spread out in all directions with speed of wave. The wavelets emanating from wave front are usually referred to as secondary wavelets. A common tangent to all these spheres	1	
	gives the new position of the wave front at a later time.		
	Incident wavefront Reflected	1	
	M A C N	1	
	Triangles EAC and BAC are congruent therefore $\angle i = \angle r$	1/2	
	iii) Position of 4 th bright fringe		
	$x_{4(bright)} = 4 \frac{D\lambda}{d}$	1/2	
	Position of 2 nd dark fringe		
	$x_{2(dark)} = \frac{3}{2} \frac{D\lambda}{d}$	1/2	
	$x_{4(bright)} - x_{2(dark)} = 5mm$		
	$4\frac{\mathrm{D}\lambda}{\mathrm{d}} - \frac{3}{2}\frac{\mathrm{D}\lambda}{\mathrm{d}} = 5 \times 10^{-3}$		
	$\lambda = 6 \times 10^{-6}$ m	1/2	
33	(a) (i) Factors on which the resonant frequency of a series LCR circuit depends 1		
	Plotting of graph 1		
	(ii) Diagram of a transformer 1		
	Working of a step-up transformer 1		
	(iii) Two causes of energy loss in a real transformer 1		
	(i) Inductance Capacitance	1/2	
	Capacitance	1/2	
	Alternatively		
	${ m v_0} = rac{1}{2\pi\sqrt{ m LC}}$		
	2π√LC		
_			



Working – The coil is rotated in the uniform magnetic field by son	ne external means.	
The rotation of the coil causes the magnetic flux through it to change	ge, so an emf is 1	
induced in the coil.		
<u>Alternatively</u>		
If a student derives $e = e_0 \sin \omega t$ give one mark for working.		
(ii) The equivalent current		
$I = \frac{q}{t} = \frac{e}{2\pi r} = \frac{ev}{2\pi r}$	1/2	
V		
Mangetic moment of revolving electron	1/2	
m = IA	/2	
$=\frac{\mathrm{ev}}{2\pi\mathrm{r}}\times\pi\mathrm{r}^2$	1/2	
2/11		
$=\frac{1}{2}$ evr	1/2	